

TLC225x-Q1, TLC225xA-Q1 Advanced LinCMOS™ RAIL-TO-RAIL VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

- Qualified for Automotive Applications
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 150 V (TLC2252/52A) and 100 V (TLC2254/54A) Using Machine Model (C = 200 pF, R = 0)
- Output Swing Includes Both Supply Rails
- Low Noise . . . 19 nV/√Hz Typ at f = 1 kHz
- Low Input Bias Current . . . 1 pA Typ
- Fully Specified for Both Single-Supply and Split-Supply Operation
- Very Low Power . . . 35 μA Per Channel Typ
- Common-Mode Input Voltage Range Includes Negative Rail
- Low Input Offset Voltage
850 μV Max at T_A = 25°C (TLC225xA)
- Macromodel Included
- Performance Upgrades for the TS27L2/L4 and TLC27L2/L4

description

The TLC2252 and TLC2254 are dual and quadruple operational amplifiers from Texas Instruments. Both devices exhibit rail-to-rail output performance for increased dynamic range in single- or split-supply applications. The TLC225x family consumes only 35 μA of supply current per channel. This micropower operation makes them good choices for battery-powered applications. The noise performance has been dramatically improved over previous generations of CMOS amplifiers. Looking at Figure 1, the TLC225x has a noise level of 19 nV/√Hz at 1 kHz; four times lower than competitive micropower solutions.

The TLC225x amplifiers, exhibiting high input impedance and low noise, are excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single or split supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLC225xA family is available and has a maximum input offset voltage of 850 μV. This family is fully characterized at 5 V and ±5 V.

The TLC2252/4 also makes great upgrades to the TLC27L2/L4 or TS27L2/L4 in standard designs. They offer increased output dynamic range, lower noise voltage, and lower input offset voltage. This enhanced feature set allows them to be used in a wider range of applications. For applications that require higher output drive and wider input voltage ranges, see the TLV2432 and TLV2442 devices. If the design requires single amplifiers, please see the TLV2211/21/31 family. These devices are single rail-to-rail operational amplifiers in the SOT-23 package. Their small size and low power consumption, make them ideal for high density, battery-powered equipment.

EQUIVALENT INPUT NOISE VOLTAGE
vs
FREQUENCY

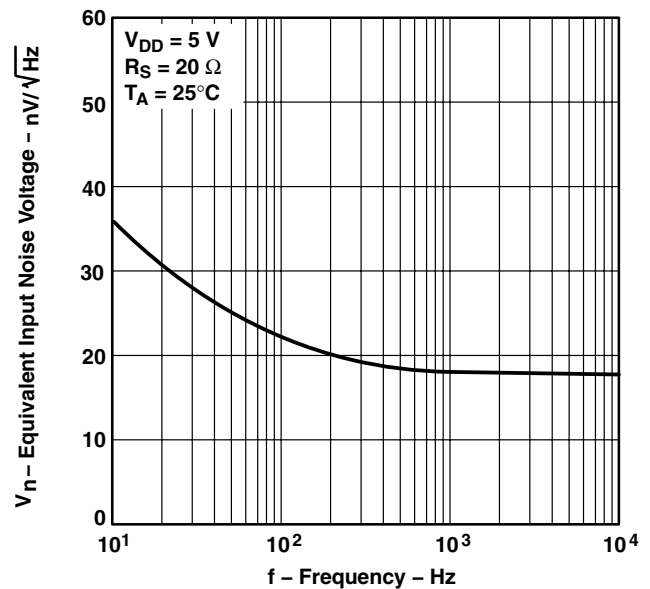


Figure 1



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Advanced LinCMOS is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265
POST OFFICE BOX 1443 • HOUSTON, TEXAS 77251-1443

Copyright © 2008 Texas Instruments Incorporated

TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

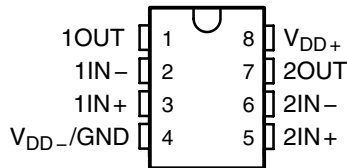
ORDERING INFORMATION†

T _A	V _{IO} max AT 25°C	PACKAGE‡		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	850 µV	SOIC (D)	Tape and reel	TLC2252AQDRQ1	2252AQ
		TSSOP (PW)	Tape and reel	TLC2252AQPWRQ1	2252AQ
	1550 µV	SOIC (D)	Tape and reel	TLC2252QDRQ1	2252Q1
		TSSOP (PW)	Tape and reel	TLC2252QPWRQ1	2252Q1
	850 µV	SOIC (D)	Tape and reel	TLC2254AQDRQ1	TLC2254AQ1
		TSSOP (PW)	Tape and reel	TLC2254AQPWRQ1	2254AQ
	1550 µV	SOIC (D)	Tape and reel	TLC2254QDRQ1	TLC2254Q1
		TSSOP (PW)	Tape and reel	TLC2254QPWRQ1	2254Q1

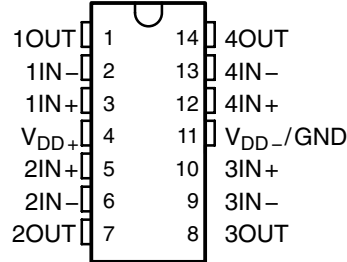
† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at <http://www.ti.com>.

‡ Package drawings, thermal data, and symbolization are available at <http://www.ti.com/packaging>.

TLC2252, TLC2252A
D OR PW PACKAGE
(TOP VIEW)



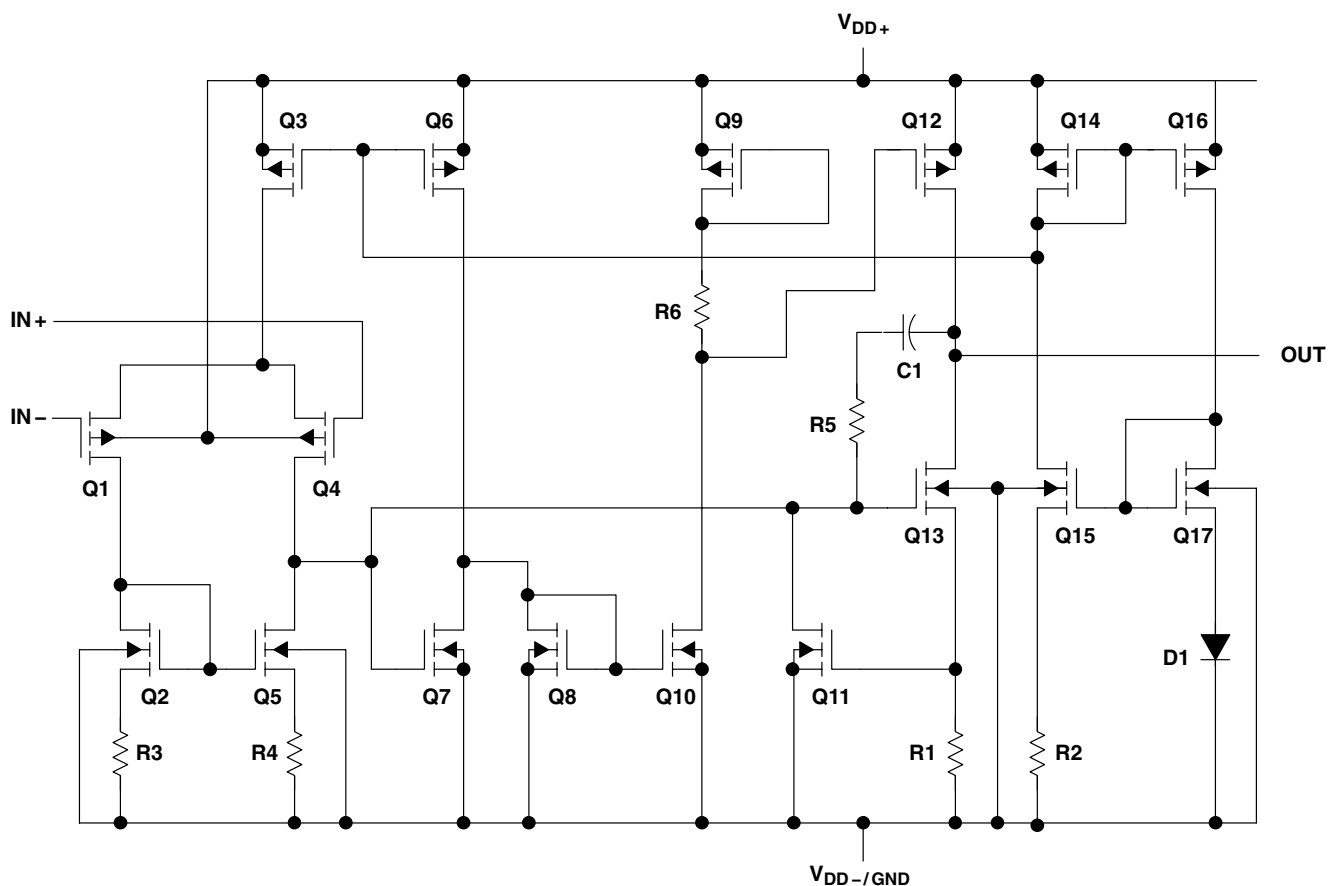
TLC2254, TLC2254A
D OR PW PACKAGE
(TOP VIEW)



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT†		
COMPONENT	TLC2252	TLC2254
Transistors	38	76
Resistors	30	56
Diodes	9	18
Capacitors	3	6

† Includes both amplifiers and all ESD, bias, and trim circuitry

TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{DD+} (see Note 1)	8 V
Supply voltage, V_{DD-} (see Note 1)	-8 V
Differential input voltage, V_{ID} (see Note 2)	± 16 V
Input voltage, V_I (any input, see Note 1)	± 8 V
Input current, I_I (each input)	± 5 mA
Output current, I_O	± 50 mA
Total current into V_{DD+}	± 50 mA
Total current out of V_{DD-}	± 50 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : Q suffix	-40°C to 125°C
Storage temperature range, T_{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{DD+} and V_{DD-} .
 2. Differential voltages are at $IN+$ with respect to $IN-$. Excessive current flows when input is brought below $V_{DD-} - 0.3$ V.
 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D-8	724 mW	5.8 mW/°C	464 mW	377 mW	144 mW
D-14	950 mW	7.6 mW/°C	608 mW	450 mW	190 mW
PW-8	525 mW	4.2 mW/°C	336 mW	273 mW	105 mW
PW-14	700 mW	5.6 mW/°C	448 mW	364 mW	140 mW

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, $V_{DD\pm}$	± 2.2	± 8	V
Input voltage range, V_I	V_{DD-}	$V_{DD+} - 1.5$	V
Common-mode input voltage, V_{IC}	V_{DD-}	$V_{DD+} - 1.5$	V
Operating free-air temperature, T_A	-40	125	°C

‡ Referenced to 2.5 V



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLC2252-Q1			TLC2252A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage		25°C	200	1500		200	850	μV	
		Full range		1750		1000			
α_{VIO} Temperature coefficient of input offset voltage		25°C to 125°C	0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{DD\pm} = \pm 2.5\text{ V}$, $V_O = 0$,	25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.5	60		0.5	60	pA	
		Full range		1000		1000			
I_{IB} Input bias current		25°C	1	60		1	60	pA	
		Full range		1000		1000			
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$, $ V_{IO} \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2		0 to 4	-0.3 to 4.2	V	
		Full range	0 to 3.5			0 to 3.5			
V_{OH} High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	4.98			4.98			V
	$I_{OH} = -75\ \mu\text{A}$	25°C	4.9	4.94		4.9	4.94		
	Full range		4.8			4.8			
V_{OL} Low-level output voltage	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 50\ \mu\text{A}$	25°C	0.01			0.01			V
	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 500\ \mu\text{A}$	25°C	0.09	0.15		0.09	0.15		
		Full range		0.15		0.15			
	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 4\text{ mA}$	25°C	0.8	1		0.7	1		
Full range			1.2		1.2				
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$, $V_O = 1\text{ V to }4\text{ V}$	$R_L = 100\text{ k}\Omega^\ddagger$	25°C	100	350		100	350	V/mV
		$R_L = 1\text{ M}\Omega^\ddagger$	Full range		10		10		
			25°C	1700			1700		
r_{id} Differential input resistance		25°C	10^{12}			10^{12}			Ω
r_{ic} Common-mode input resistance		25°C	10^{12}			10^{12}			Ω
c_{ic} Common-mode input capacitance	$f = 10\text{ kHz}$, $f = 10\text{ kHz}$,	25°C	8			8			pF
z_o Closed-loop output impedance	$f = 25\text{ kHz}$, $A_V = 10$	25°C	200			200			Ω
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$, $V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$	25°C	70	83		70	83	dB	
		Full range		70		70			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 4.4\text{ V to }16\text{ V}$, $V_{IC} = V_{DD}/2$, No load	25°C	80	95		80	95	dB	
		Full range		80		80			
I_{DD} Supply current	$V_O = 2.5\text{ V}$, No load	25°C	70	125		70	125	μA	
		Full range		150		150			

† Full range is -40°C to 125°C for Q suffix.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

operating characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A †	TLC2252-Q1			TLC2252A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = 0.5\text{ V to }3.5\text{ V}$, $R_L = 100\text{ k}\Omega^\ddagger$, $C_L = 100\text{ pF}^\ddagger$	25°C	0.07	0.12		0.07	0.12		$\text{V}/\mu\text{s}$
		Full range	0.05			0.05			
V_n	Equivalent input noise voltage $f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C	36			36			$\text{nV}/\sqrt{\text{Hz}}$
		25°C	19			19			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage $f = 0.1\text{ Hz to }1\text{ Hz}$ $f = 0.1\text{ Hz to }10\text{ Hz}$	25°C	0.7			0.7			μV
		25°C	1.1			1.1			
I_n	Equivalent input noise current	25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V to }2.5\text{ V}$, $f = 10\text{ kHz}$, $R_L = 50\text{ k}\Omega^\ddagger$	25°C	$A_V = 1$			0.2%			
			$A_V = 10$			1%			
	Gain-bandwidth product $f = 50\text{ kHz}$, $C_L = 100\text{ pF}^\ddagger$	25°C	$R_L = 50\text{ k}\Omega^\ddagger$			0.2			MHz
BOM	Maximum output-swing bandwidth $V_{O(PP)} = 2\text{ V}$, $R_L = 50\text{ k}\Omega^\ddagger$	25°C	$A_V = 1$, $C_L = 100\text{ pF}^\ddagger$			30			kHz
ϕ_m	Phase margin at unity gain $R_L = 50\text{ k}\Omega^\ddagger$, $C_L = 100\text{ pF}^\ddagger$	25°C	63°			63°			
		25°C	15			15			dB

† Full range is -40°C to 125°C for Q suffix.

‡ Referenced to 2.5 V



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

electrical characteristics at specified free-air temperature, $V_{DD\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLC2252-Q1			TLC2252A-Q1			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	200		1500	200		850	μV	
		Full range	1750			1000				
α_{VIO} Temperature coefficient of input offset voltage		25°C to 125°C	0.5			0.5			$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$	
I_{IO} Input offset current		25°C	0.5	60		0.5	60		pA	
		Full range	1000			1000				
I_{IB} Input bias current	25°C	1	60		1	60		pA		
	Full range	1000			1000					
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega, V_{IO} \leq 5\ \text{mV}$	25°C	-5 to 4	-5.3 to 4.2	-5 to 4	-5.3 to 4.2			V	
		Full range	-5 to 3.5	-5 to 3.5	-5 to 3.5	-5 to 3.5				
V_{OM+} Maximum positive peak output voltage	$I_O = -20\ \mu\text{A}$	25°C	4.98			4.98			V	
		25°C	4.9	4.93		4.9	4.93			
		Full range	4.7			4.7				
		25°C	4.8	4.86		4.8	4.86			
V_{OM-} Maximum negative peak output voltage	$V_{IC} = 0, I_O = 50\ \mu\text{A}$	25°C	-4.99			-4.99			V	
		25°C	-4.85	-4.91		-4.85	-4.91			
	Full range	-4.85			-4.85					
	$V_{IC} = 0, I_O = 4\ \text{mA}$	25°C	-4	-4.3		-4	-4.3			
		Full range	-3.8			-3.8				
	A_{VD} Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}$	$R_L = 100\ \text{k}\Omega$	25°C	40	150		40		150
Full range				10			10			
$R_L = 1\ \text{M}\Omega$			25°C	3000			3000			
r_{id} Differential input resistance		25°C	10^{12}			10^{12}			Ω	
r_{ic} Common-mode input resistance		25°C	10^{12}			10^{12}			Ω	
c_{ic} Common-mode input capacitance	$f = 10\ \text{kHz}, \text{ P package}$	25°C	8			8			pF	
z_o Closed-loop output impedance	$f = 25\ \text{kHz}, A_V = 10$	25°C	190			190			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = -5\ \text{V to } 2.7\ \text{V}, V_O = 0, R_S = 50\ \Omega$	25°C	75	88		75	88		dB	
		Full range	75			75				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	$V_{DD} = \pm 2.2\ \text{V to } \pm 8\ \text{V}, V_{IC} = 0, \text{ No load}$	25°C	80	95		80	95		dB	
		Full range	80			80				
I_{DD} Supply current	$V_O = 2.5\ \text{V}, \text{ No load}$	25°C	80	125		80	125		μA	
		Full range	150			150				

† Full range is -40°C to 125°C for Q suffix.

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

operating characteristics at specified free-air temperature, $V_{DD\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLC2252-Q1			TLC2252A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = \pm 2\text{ V}$, $C_L = 100\text{ pF}$, $R_L = 100\text{ k}\Omega$	25°C	0.07	0.12		0.07	0.12		V/ μs
		Full range	0.05			0.05			
V_n	Equivalent input noise voltage	f = 10 Hz	38			38			nV/ $\sqrt{\text{Hz}}$
		f = 1 kHz	19			19			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz	0.8			0.8			μV
		f = 0.1 Hz to 10 Hz	1.1			1.1			
I_n	Equivalent input noise current	25°C	0.6			0.6			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise $V_O = \pm 2.3\text{ V}$, $R_L = 50\text{ k}\Omega$, f = 10 kHz	$A_V = 1$	0.2%			0.2%			
		$A_V = 10$	1%			1%			
	Gain-bandwidth product f = 10 kHz, $C_L = 100\text{ pF}$, $R_L = 50\text{ k}\Omega$	25°C	0.21			0.21			MHz
BOM	Maximum output-swing bandwidth $V_{O(PP)} = 4.6\text{ V}$, $R_L = 50\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	14			14			kHz
ϕ_m	Phase margin at unity gain $R_L = 50\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C	63°			63°			
		25°C	15			15			dB

† Full range is -40°C to 125°C for Q suffix.



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLC2254-Q1			TLC2254A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage		25°C		200	1500		200	850	μV
		Full range			1750			1000	
α_{VIO} Temperature coefficient of input offset voltage	$V_{DD\pm} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C to 125°C		0.5			0.5		$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)		25°C		0.003			0.003		$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C		0.5	60		0.5	60	pA
		125°C			1000			1000	
I_{IB} Input bias current	25°C		1	60		1	60	pA	
	125°C			1000			1000		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$, $ V_{IO} \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2		0 to 4	-0.3 to 4.2	V	
		Full range	0 to 3.5			0 to 3.5			
V_{OH} High-level output voltage	$I_{OH} = -20\ \mu\text{A}$ $I_{OH} = -75\ \mu\text{A}$ $I_{OH} = -150\ \mu\text{A}$	25°C		4.98			4.98	V	
		25°C		4.9	4.94		4.9		4.94
		Full range		4.8			4.8		
V_{OL} Low-level output voltage	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 50\ \mu\text{A}$ $V_{IC} = 2.5\text{ V}$, $I_{OL} = 500\ \mu\text{A}$ $V_{IC} = 2.5\text{ V}$, $I_{OL} = 4\text{ mA}$	25°C		0.01			0.01	V	
		25°C		0.09	0.15		0.09		0.15
		Full range			0.15				0.15
		25°C		0.8	1		0.7		1
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$, $V_O = 1\text{ V to }4\text{ V}$	$R_L = 100\text{ k}\Omega^\ddagger$	25°C	100	350		100	350	V/mV
			Full range		10			10	
		$R_L = 1\text{ M}\Omega^\ddagger$	25°C		1700			1700	
$r_{i(d)}$ Differential input resistance		25°C		10^{12}			10^{12}	Ω	
$r_{i(c)}$ Common-mode input resistance		25°C		10^{12}			10^{12}	Ω	
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$, N package	25°C		8			8	pF	
z_o Closed-loop output impedance	$f = 25\text{ kHz}$, $A_V = 10$	25°C		200			200	Ω	
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$, $V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$	25°C		70	83		70	83	dB
		Full range		70			70		
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 4.4\text{ V to }16\text{ V}$, $V_{IC} = V_{DD}/2$, No load	25°C		80	95		80	95	dB
		Full range		80			80		
I_{DD} Supply current (four amplifiers)	$V_O = 2.5\text{ V}$, No load	25°C		140	250		140	250	μA
		Full range			300			300	

† Full range is -40°C to 125°C for Q suffix.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

operating characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$

PARAMETER	TEST CONDITIONS		T_A †	TLC2254-Q1			TLC2254A-Q1			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	$V_O = 0.5\text{ V to }3.5\text{ V}$, $R_L = 100\text{ k}\Omega^\ddagger$, $C_L = 100\text{ pF}^\ddagger$	25°C	0.07	0.12		0.07	0.12		$\text{V}/\mu\text{s}$
			Full range	0.05			0.05			
V_n	Equivalent input noise voltage	$f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C	36			36			$\text{nV}/\sqrt{\text{Hz}}$
			25°C	19			19			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$ $f = 0.1\text{ Hz to }10\text{ Hz}$	25°C	0.7			0.7			μV
			25°C	1.1			1.1			
I_n	Equivalent input noise current		25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O = 0.5\text{ V to }2.5\text{ V}$, $f = 20\text{ kHz}$, $R_L = 50\text{ k}\Omega^\ddagger$	25°C	$A_V = 1$			0.2%			
				$A_V = 10$			1%			
	Gain-bandwidth product	$f = 50\text{ kHz}$, $C_L = 100\text{ pF}^\ddagger$	25°C	$R_L = 50\text{ k}\Omega^\ddagger$			0.2			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $R_L = 50\text{ k}\Omega^\ddagger$	25°C	$A_V = 1$, $C_L = 100\text{ pF}^\ddagger$			30			kHz
ϕ_m	Phase margin at unity gain	$R_L = 50\text{ k}\Omega^\ddagger$, $C_L = 100\text{ pF}^\ddagger$	25°C	63°			63°			
	Gain margin		25°C	15			15			dB

† Full range is -40°C to 125°C for Q suffix.

‡ Referenced to 2.5 V



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

electrical characteristics at specified free-air temperature, $V_{DD\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLC2254-Q1			TLC2254A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage		25°C	200		1500	200		850	μV
		Full range	1750			1000			
α_{VIO} Temperature coefficient of input offset voltage		25°C to 125°C	0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
I_{IO} Input offset current		25°C	0.5	60	0.5	60	pA		
		125°C	1000			1000			
I_{IB} Input bias current		25°C	1	60	1	60	pA		
		125°C	1000			1000			
V_{ICR} Common-mode input voltage range		$R_S = 50\ \Omega, V_{IO} \leq 5\ \text{mV}$	25°C	-5 to 4	-5.3 to 4.2	-5 to 4	-5.3 to 4.2	V	
	Full range		-5 to 3.5	-5 to 3.5	-5 to 3.5	-5 to 3.5			
V_{OM+} Maximum positive peak output voltage	$I_O = -20\ \mu\text{A}$	25°C	4.98		4.98		V		
		25°C	4.9	4.93	4.9	4.93			
		Full range	4.7			4.7			
		25°C	4.8	4.86	4.8	4.86			
V_{OM-} Maximum negative peak output voltage	$V_{IC} = 0, I_O = 50\ \mu\text{A}$	25°C	-4.99		-4.99		V		
		25°C	-4.85	-4.91	-4.85	-4.91			
	Full range	-4.85			-4.85				
	$V_{IC} = 0, I_O = 500\ \mu\text{A}$	25°C	-4	-4.3	-4	-4.3			
		Full range	-3.8			-3.8			
	A_{VD} Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}$	$R_L = 100\ \text{k}\Omega$	25°C	40	150		40	150
Full range				10			10		
$R_L = 1\ \text{M}\Omega$			25°C	3000			3000		
$r_{i(d)}$ Differential input resistance		25°C	10^{12}			10^{12}			Ω
$r_{i(c)}$ Common-mode input resistance		25°C	10^{12}			10^{12}			Ω
$c_{i(c)}$ Common-mode input capacitance	$f = 10\ \text{kHz}, \text{ N package}$	25°C	8			8			pF
z_o Closed-loop output impedance	$f = 25\ \text{kHz}, A_V = 10$	25°C	190			190			Ω
CMRR Common-mode rejection ratio	$V_{IC} = -5\ \text{V to } 2.7\ \text{V}, V_O = 0, R_S = 50\ \Omega$	25°C	75	88	75	88	dB		
		Full range	75			75			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	$V_{DD\pm} = \pm 2.2\ \text{V to } \pm 8\ \text{V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C	80	95	80	95	dB		
		Full range	80			80			
I_{DD} Supply current (four amplifiers)	$V_O = 0, \text{ No load}$	25°C	160	250	160	250	μA		
		Full range	300			300			

† Full range is -40°C to 125°C for Q suffix.

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

operating characteristics at specified free-air temperature, $V_{DD\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS		T_A^\dagger	TLC2254-Q1			TLC2254A-Q1			UNIT	
				MIN	TYP	MAX	MIN	TYP	MAX		
SR	Slew rate at unity gain	$V_O = \pm 2\text{ V}$, $C_L = 100\text{ pF}$	$R_L = 100\text{ k}\Omega$	25°C	0.07	0.12		0.07	0.12	$\text{V}/\mu\text{s}$	
				Full range	0.05			0.05			
V_n	Equivalent input noise voltage	$f = 10\text{ Hz}$		25°C	38			38			$\text{nV}/\sqrt{\text{Hz}}$
				$f = 1\text{ kHz}$		19			19		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		25°C	0.8			0.8			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		1.1			1.1				
I_n	Equivalent input noise current			25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O = \pm 2.3\text{ V}$, $R_L = 50\text{ k}\Omega$, $f = 20\text{ kHz}$	$A_V = 1$	25°C	0.2%			0.2%			
			$A_V = 10$		1%			1%			
	Gain-bandwidth product	$f = 10\text{ kHz}$, $C_L = 100\text{ pF}$	$R_L = 50\text{ k}\Omega$	25°C	0.21			0.21			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 4.6\text{ V}$, $R_L = 50\text{ k}\Omega$	$A_V = 1$, $C_L = 100\text{ pF}$	25°C	14			14			kHz
ϕ_m	Phase margin at unity gain	$R_L = 50\text{ k}\Omega$	$C_L = 100\text{ pF}$	25°C	63°			63°			
	Gain margin			25°C	15			15			dB

† Full range is -40°C to 125°C for Q suffix.



TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE
V_{IO}	Input offset voltage	Distribution vs Common-mode input voltage 2 – 5 6, 7
α_{VIO}	Input offset voltage temperature coefficient	Distribution 8 – 11
I_{IB}/I_{IO}	Input bias and input offset currents	vs Free-air temperature 12
V_I	Input voltage range	vs Supply voltage vs Free-air temperature 13 14
V_{OH}	High-level output voltage	vs High-level output current 15
V_{OL}	Low-level output voltage	vs Low-level output current 16, 17
V_{OM+}	Maximum positive peak output voltage	vs Output current 18
V_{OM-}	Maximum negative peak output voltage	vs Output current 19
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency 20
I_{OS}	Short-circuit output current	vs Supply voltage vs Free-air temperature 21 22
V_O	Output voltage	vs Differential input voltage 23, 24
	Differential gain	vs Load resistance 25
A_{VD}	Large-signal differential voltage amplification	vs Frequency vs Free-air temperature 26, 27 28, 29
z_o	Output impedance	vs Frequency 30, 31
CMRR	Common-mode rejection ratio	vs Frequency vs Free-air temperature 32 33
k_{SVR}	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature 34, 35 36
I_{DD}	Supply current	vs Supply voltage vs Free-air temperature 37 38
SR	Slew rate	vs Load capacitance vs Free-air temperature 39 40
V_O	Inverting large-signal pulse response	41, 42
V_O	Voltage-follower large-signal pulse response	43, 44
V_O	Inverting small-signal pulse response	45, 46
V_O	Voltage-follower small-signal pulse response	47, 48
V_n	Equivalent input noise voltage	vs Frequency 49, 50
	Noise voltage (referred to input)	Over a 10-second period 51
	Integrated noise voltage	vs Frequency 52
THD + N	Total harmonic distortion plus noise	vs Frequency 53
	Gain-bandwidth product	vs Free-air temperature vs Supply voltage 54 55
ϕ_m	Phase margin	vs Frequency vs Load capacitance 26, 27 56
A_m	Gain margin	vs Load capacitance 57
B_1	Unity-gain bandwidth	vs Load capacitance 58
	Overestimation of phase margin	vs Load capacitance 59

TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

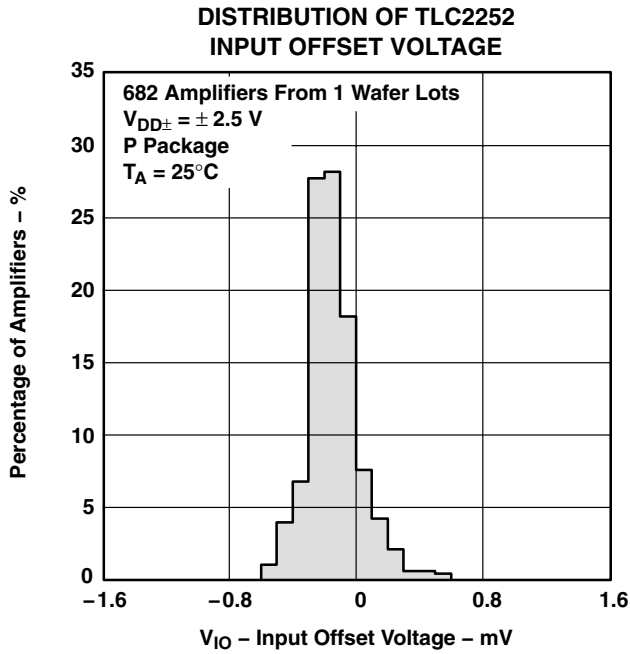


Figure 2

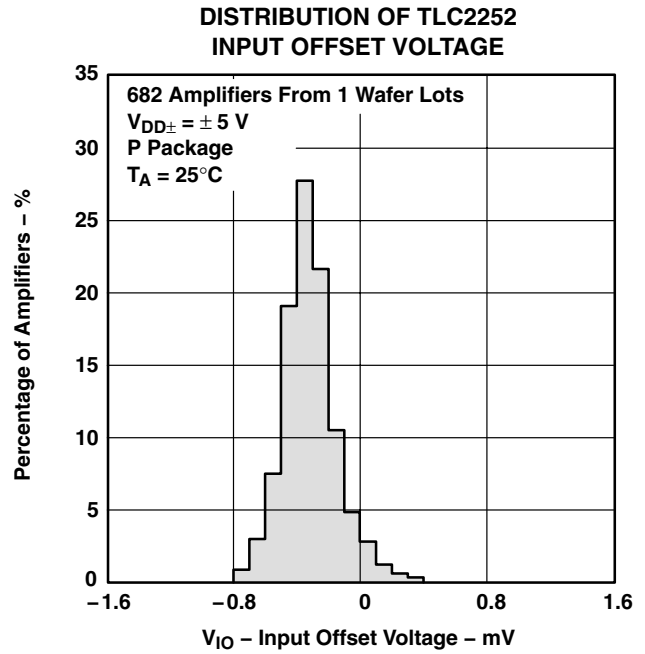


Figure 3

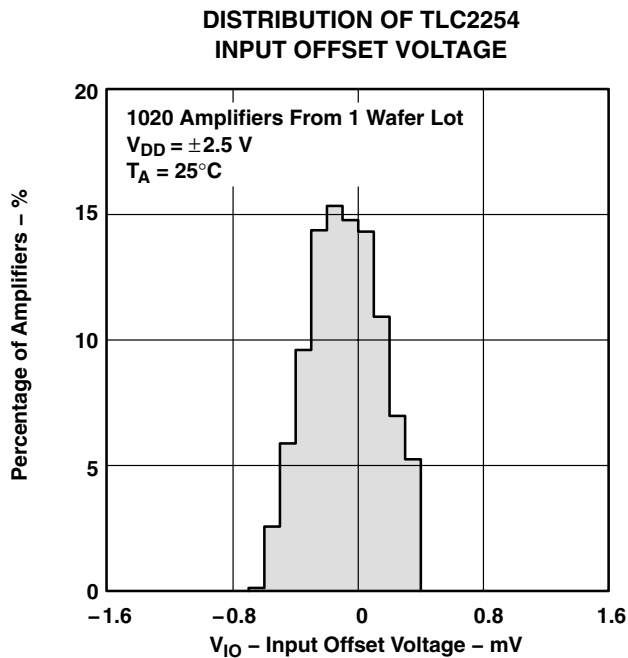


Figure 4

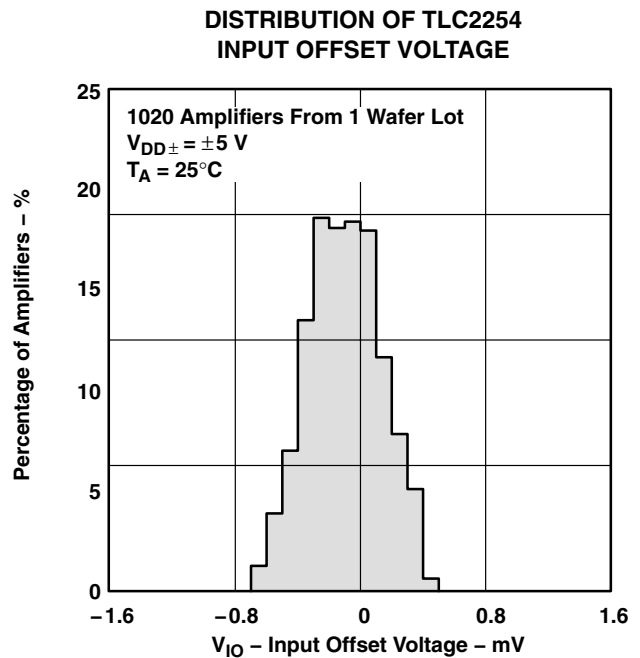
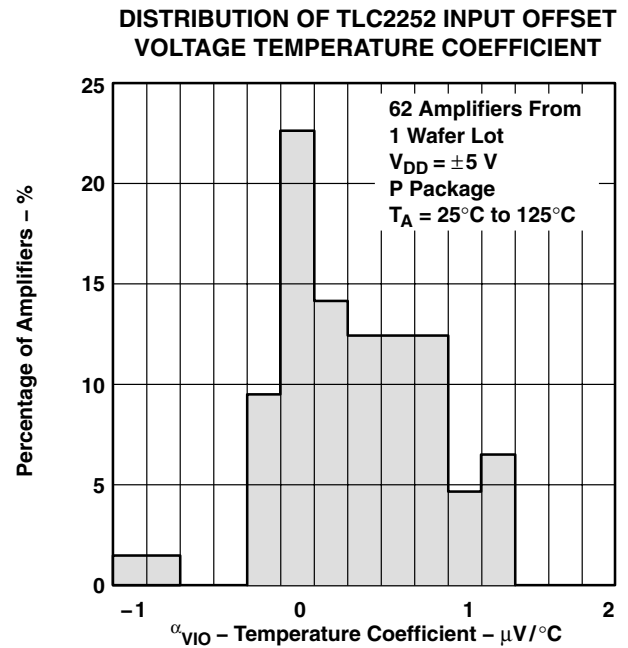
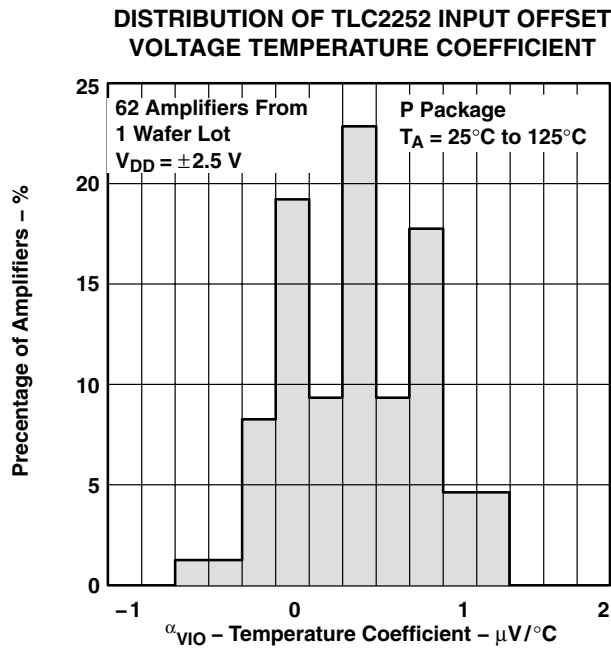
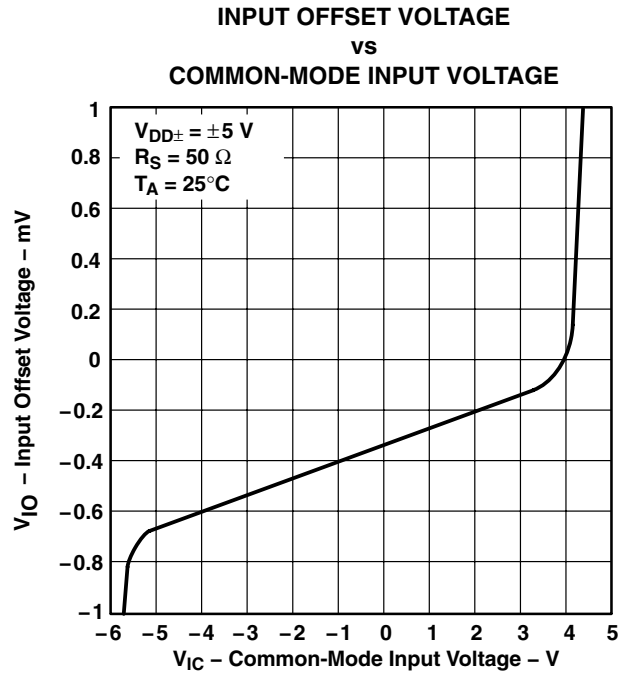
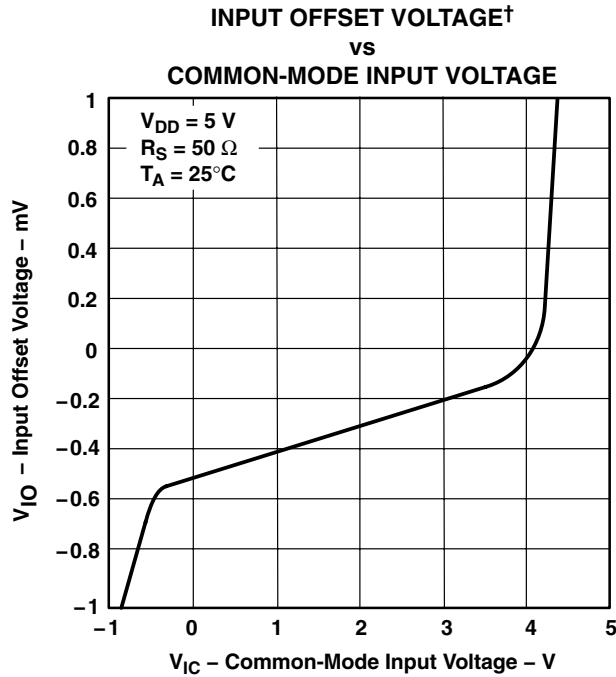


Figure 5



TYPICAL CHARACTERISTICS



† For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.

TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLC2254 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

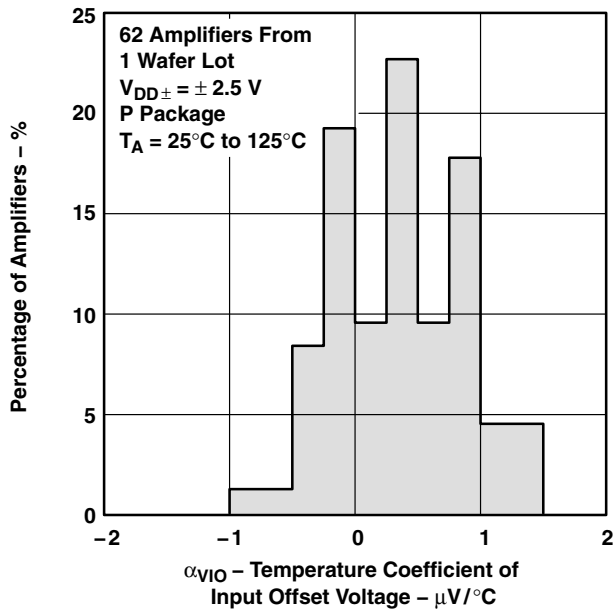


Figure 10

DISTRIBUTION OF TLC2254 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

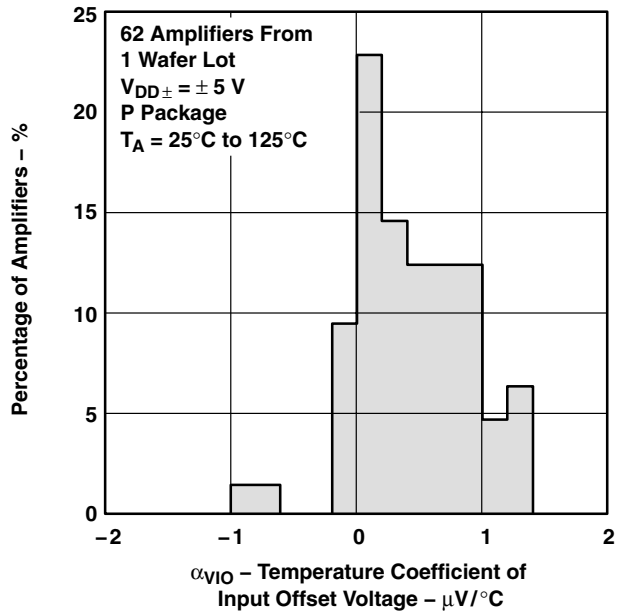


Figure 11

INPUT BIAS AND INPUT OFFSET CURRENTS†
vs
FREE-AIR TEMPERATURE

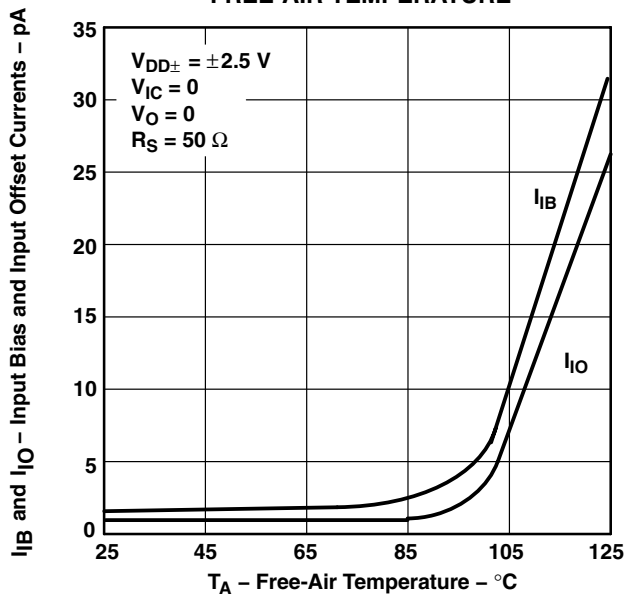


Figure 12

INPUT VOLTAGE RANGE
vs
SUPPLY VOLTAGE

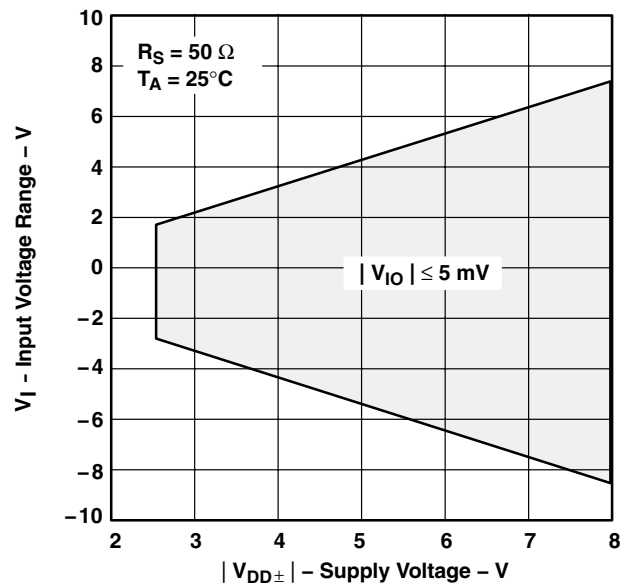


Figure 13

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

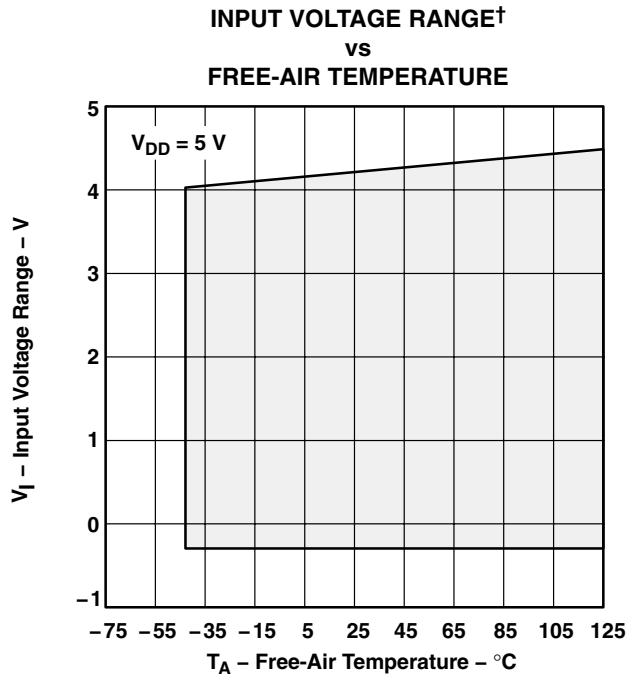


Figure 14

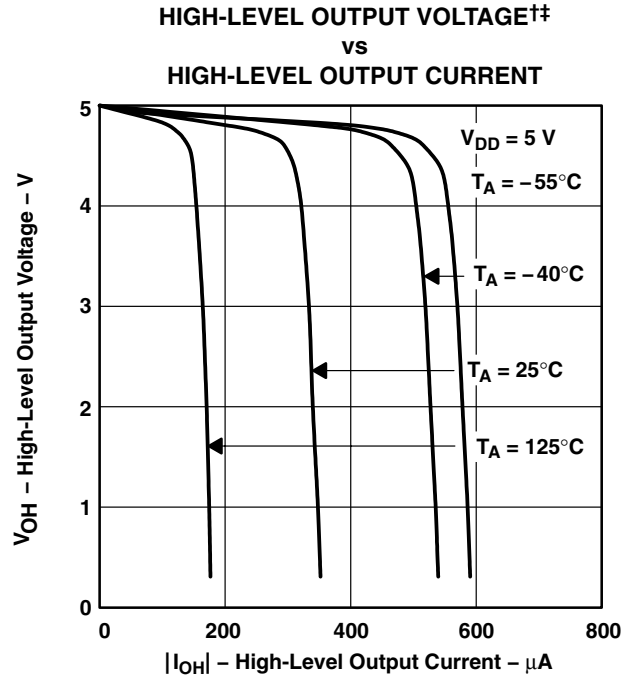


Figure 15

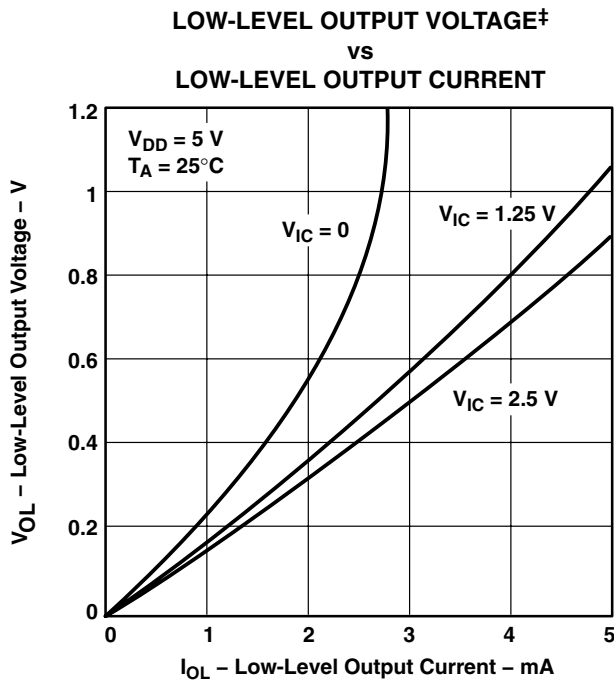


Figure 16

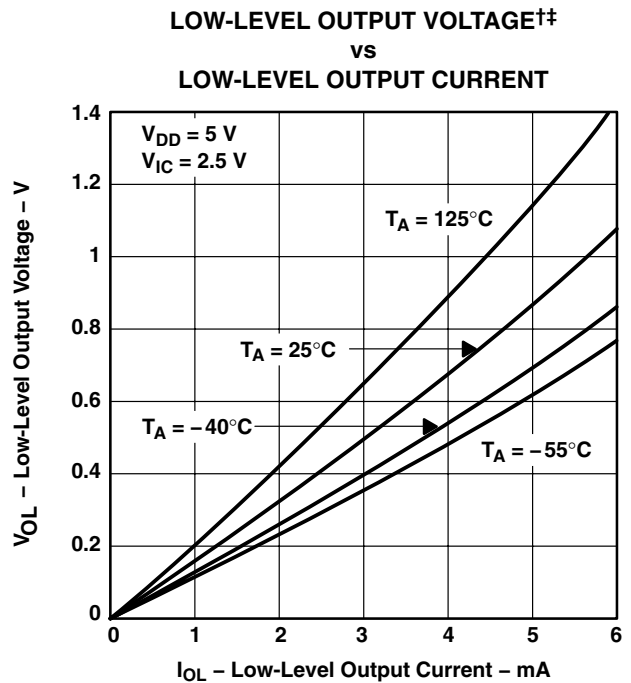


Figure 17

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.

TLC225x-Q1, TLC225xA-Q1

Advanced LinCMOS™ RAIL-TO-RAIL

VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE†
vs
OUTPUT CURRENT

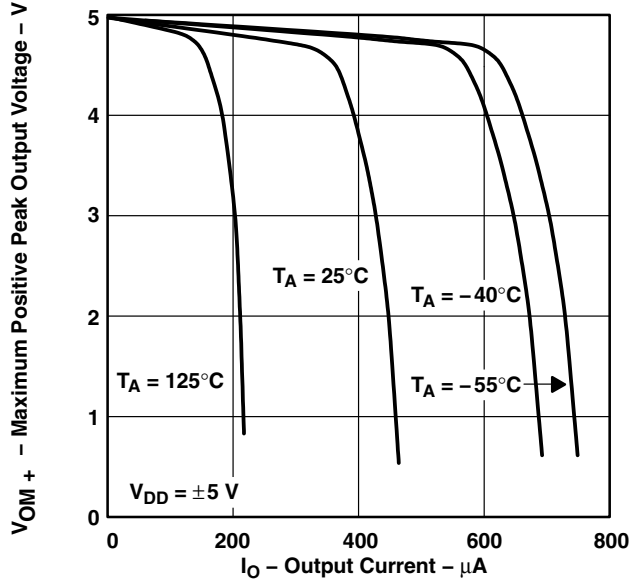


Figure 18

MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE†
vs
OUTPUT CURRENT

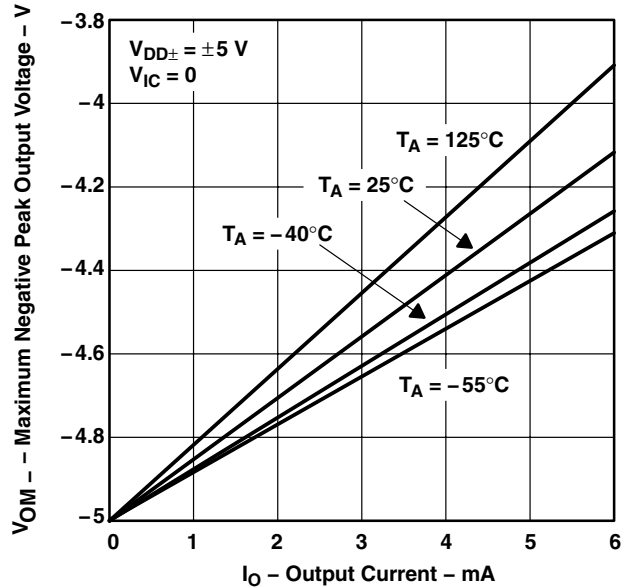


Figure 19

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE‡
vs
FREQUENCY

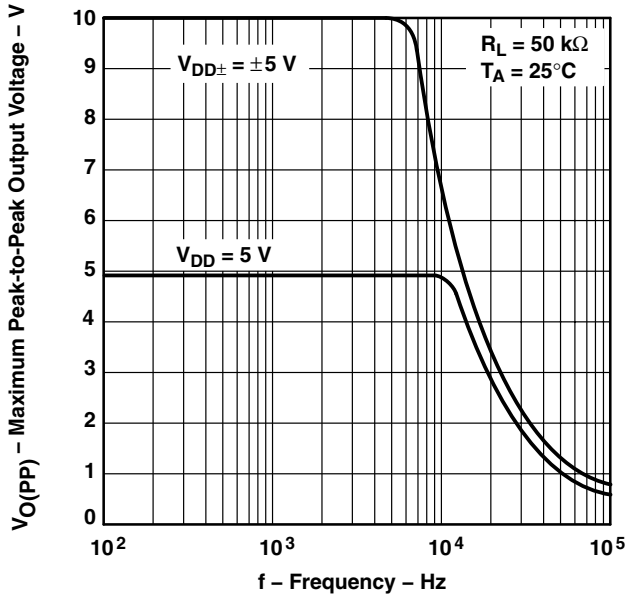


Figure 20

SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE

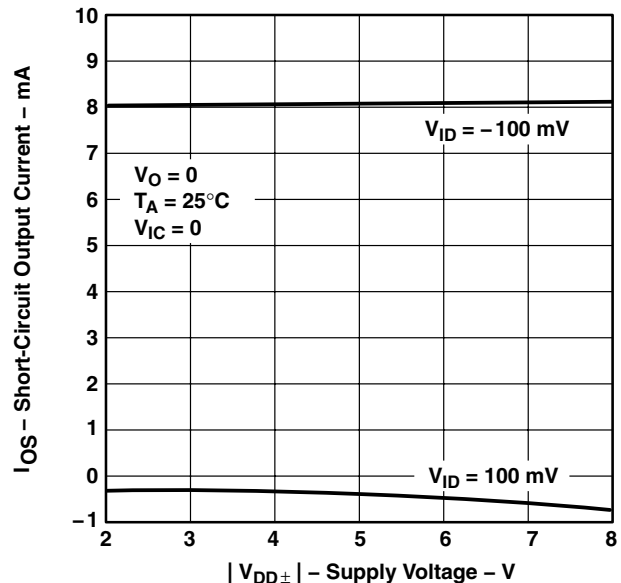


Figure 21

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V .



TYPICAL CHARACTERISTICS

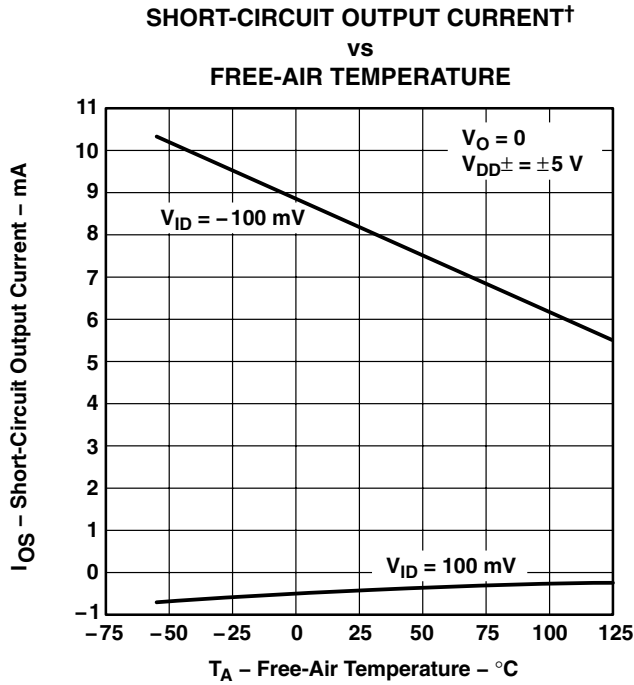


Figure 22

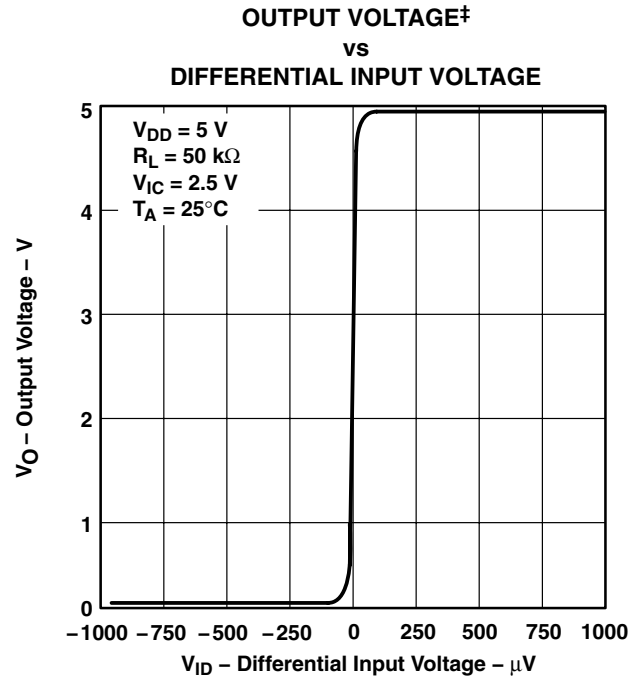


Figure 23

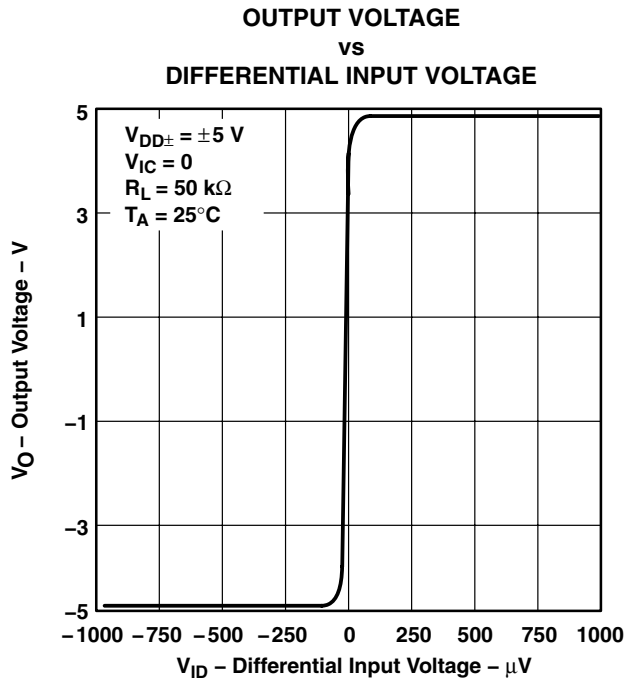


Figure 24

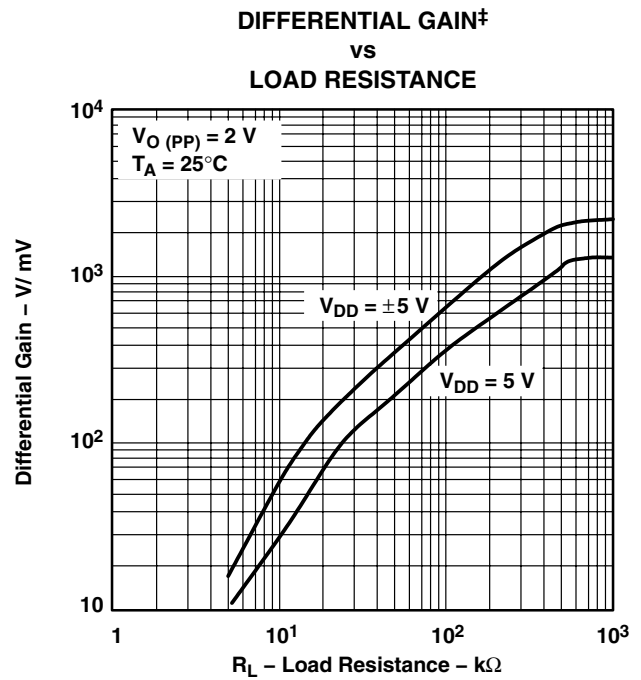


Figure 25

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.

TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN†
vs
FREQUENCY

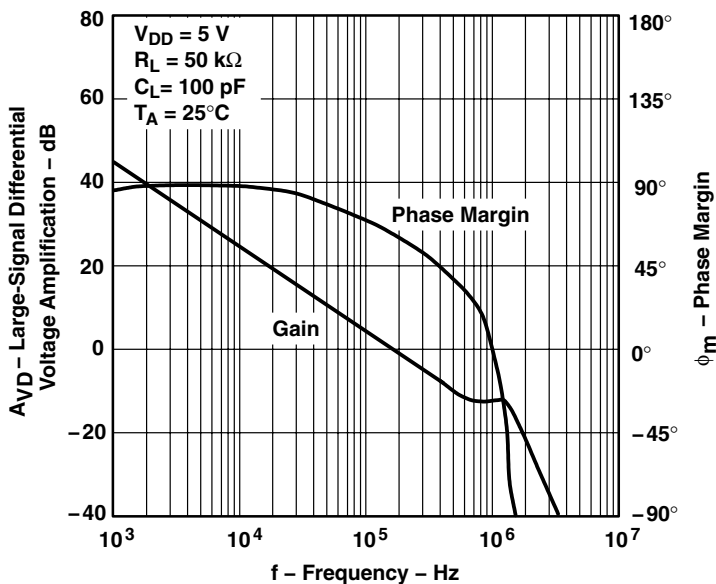


Figure 26

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN
vs
FREQUENCY

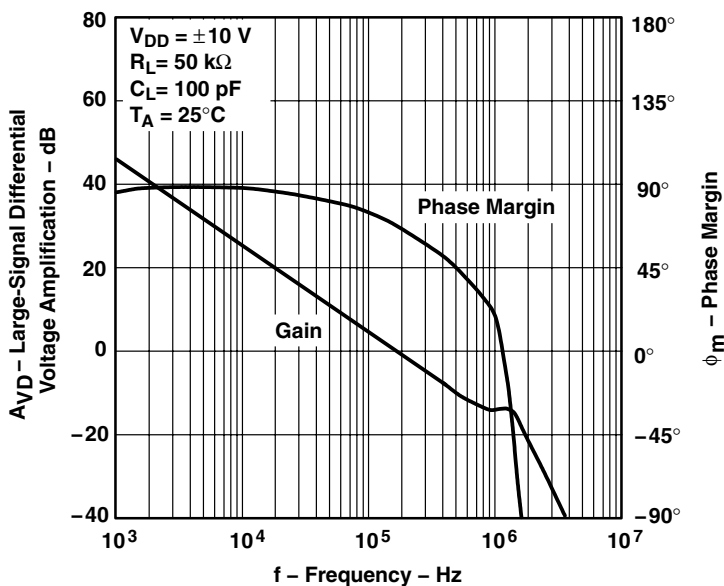
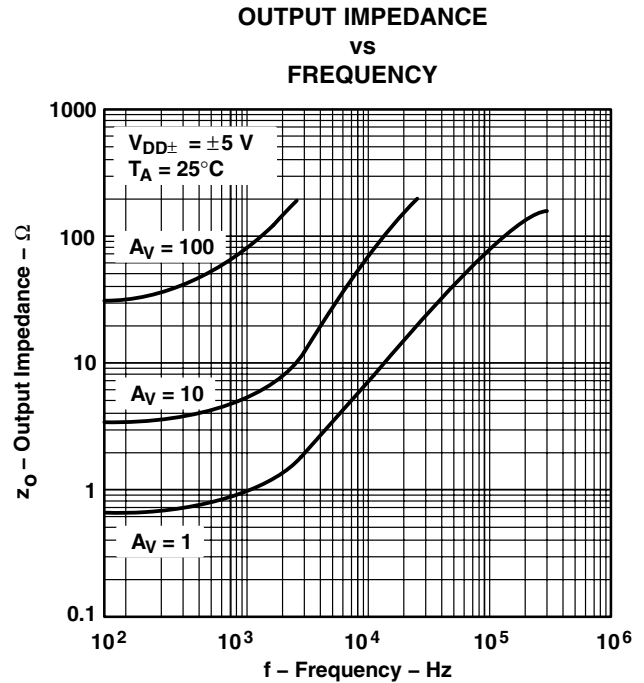
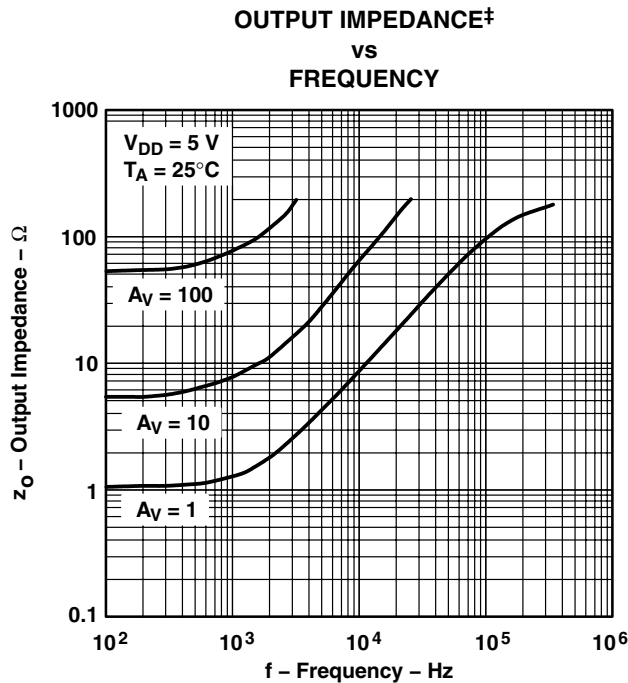
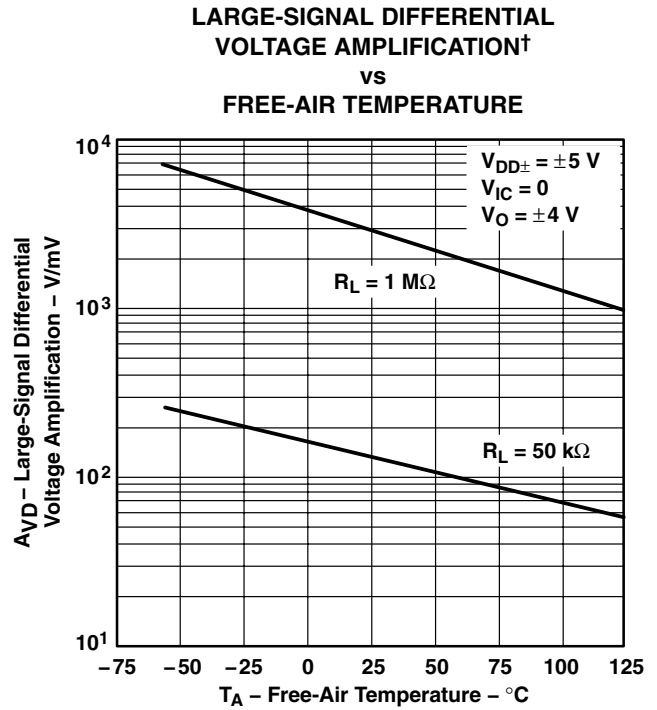
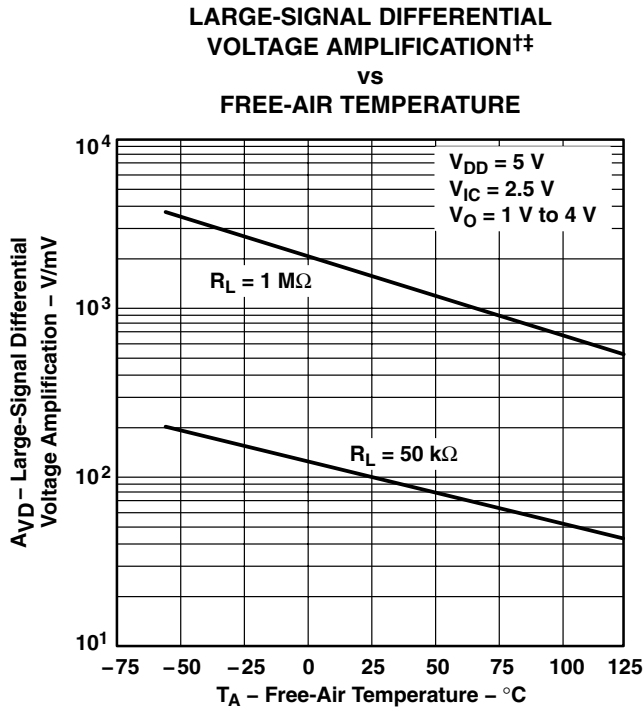


Figure 27

† For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.



TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.

TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

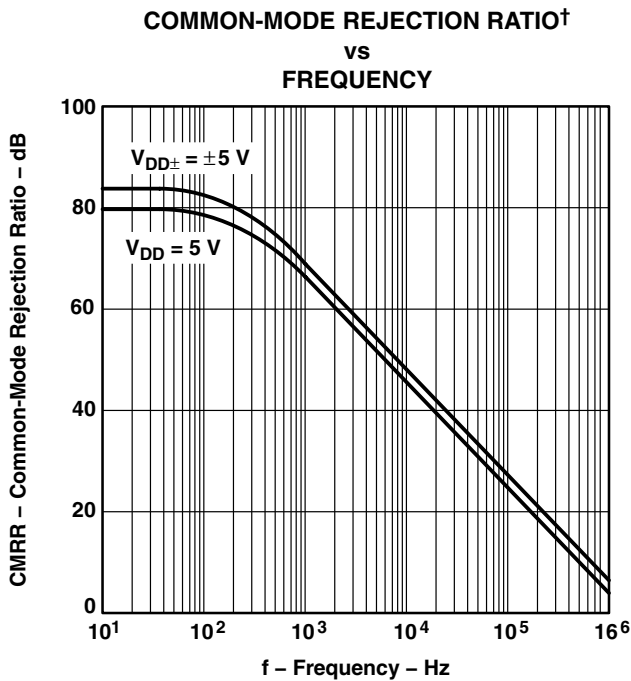


Figure 32

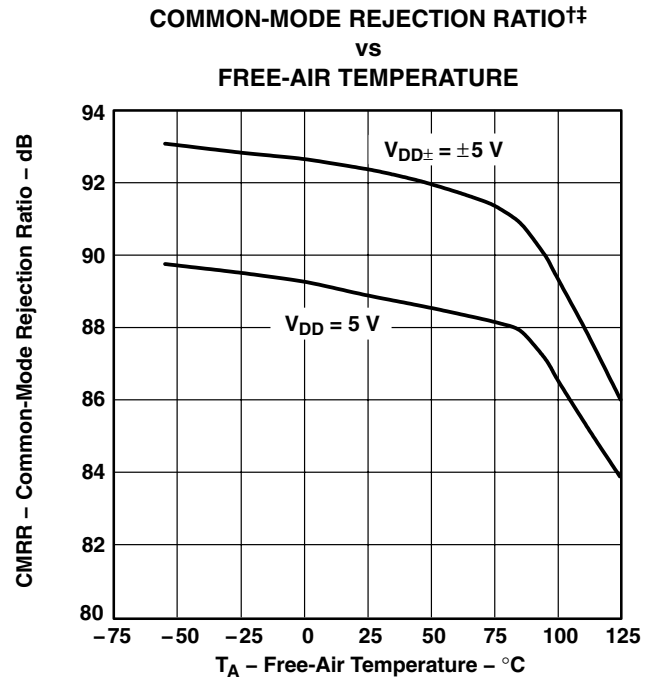


Figure 33

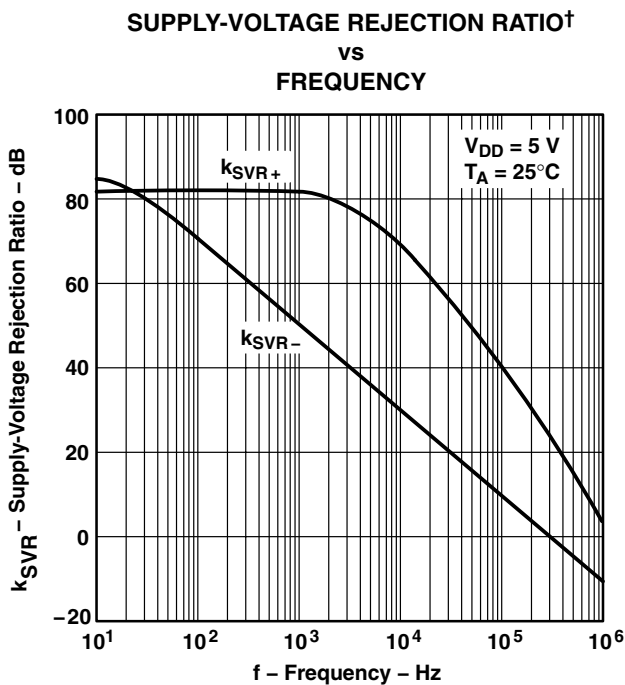


Figure 34

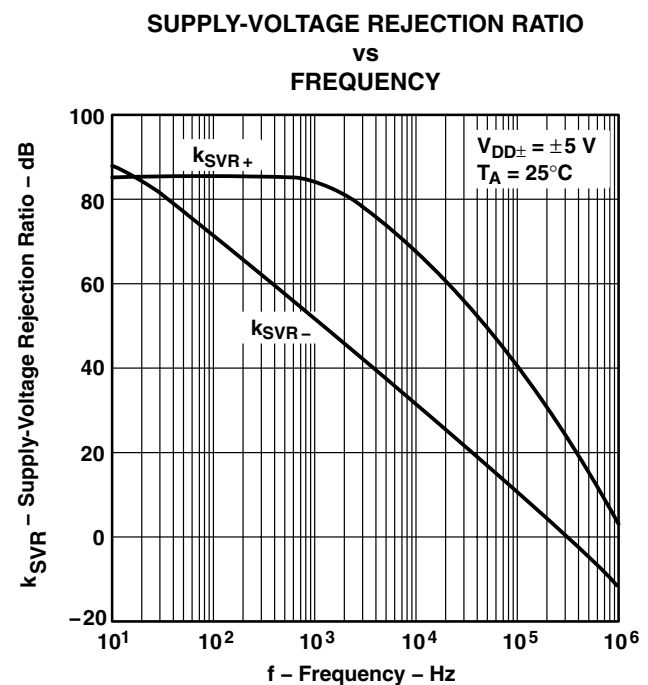


Figure 35

† For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.

‡ Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

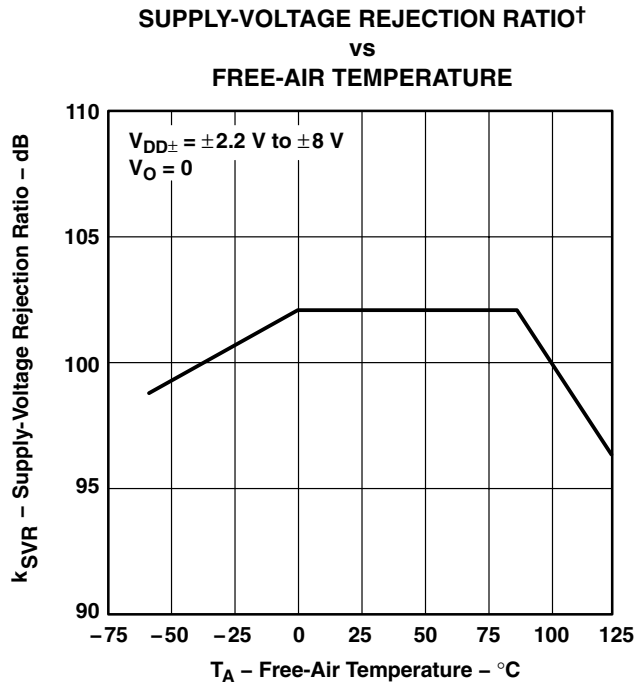


Figure 36

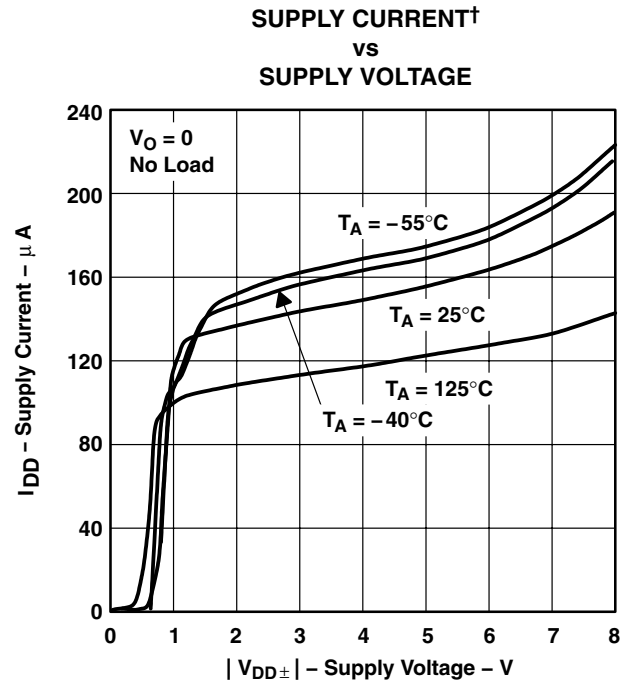


Figure 37

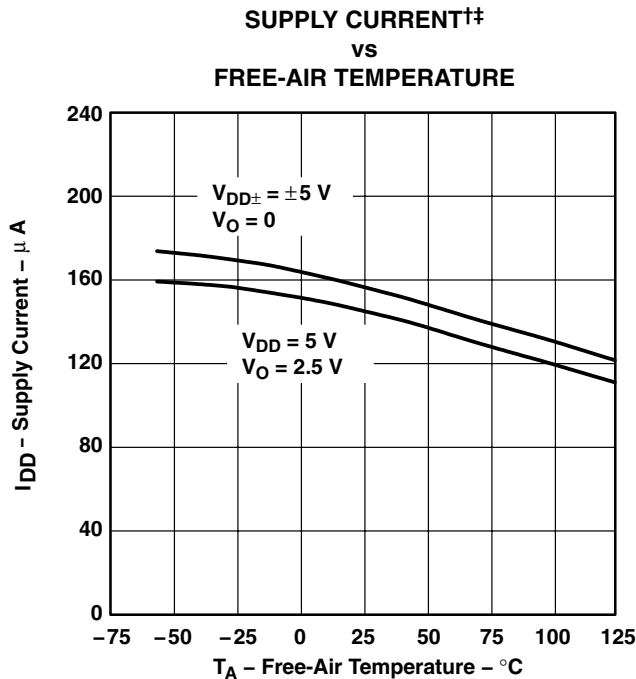


Figure 38

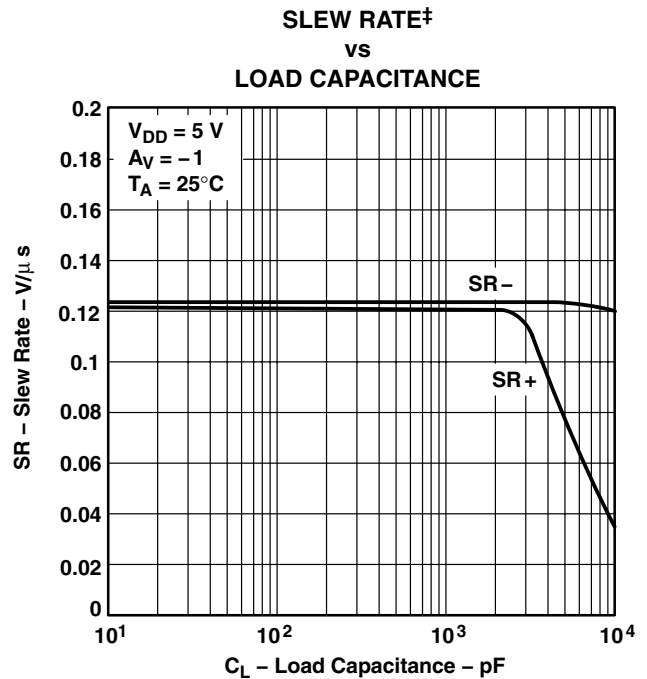


Figure 39

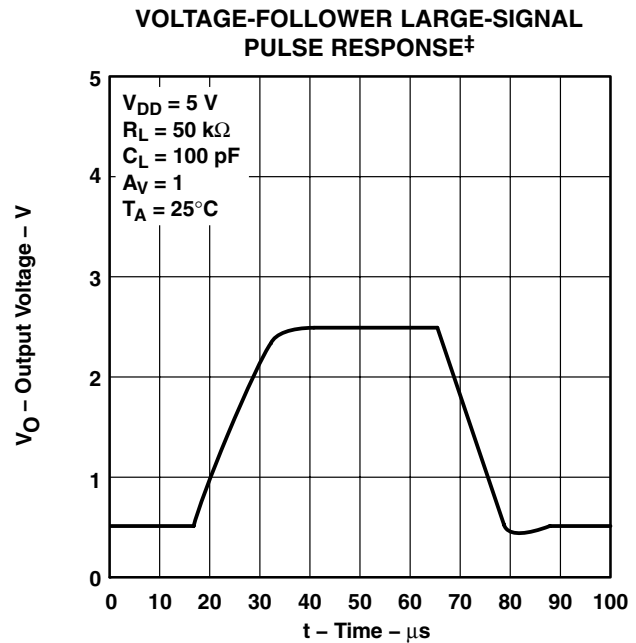
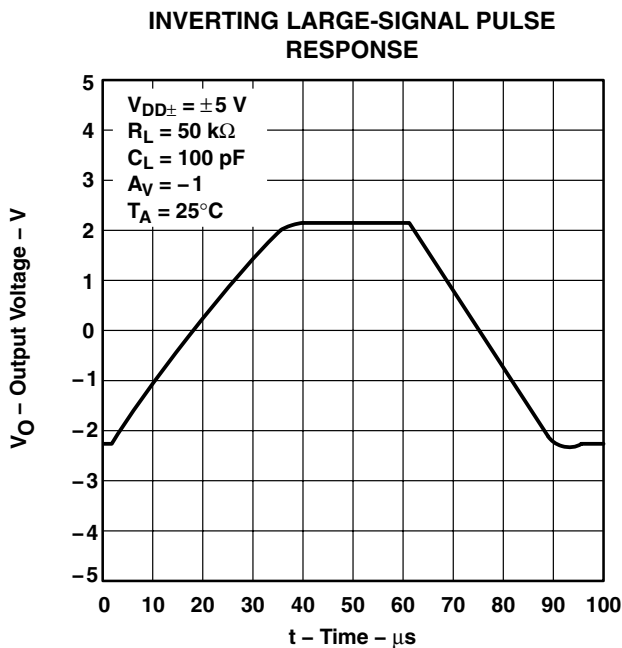
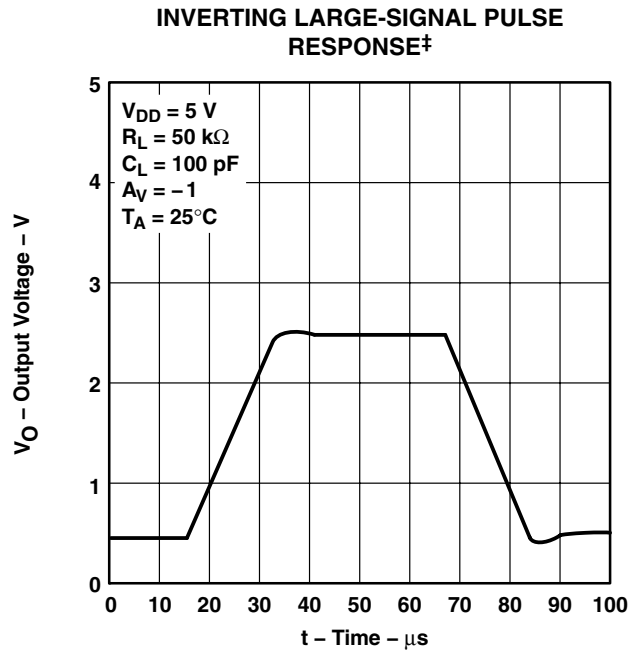
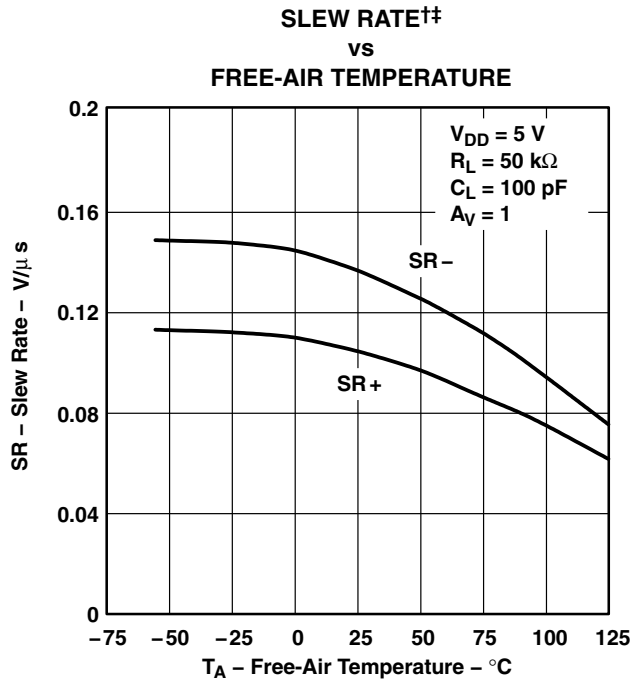
† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where $V_{DD} = 5 \text{ V}$, all loads are referenced to 2.5 V.

TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.



TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER LARGE-SIGNAL
 PULSE RESPONSE

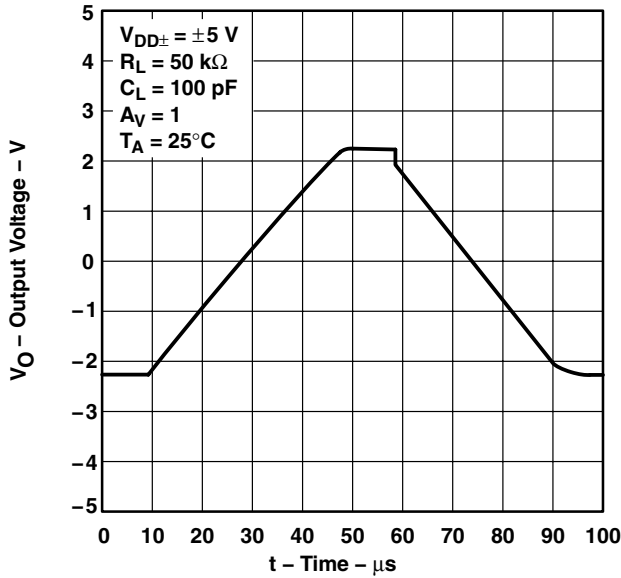


Figure 44

INVERTING SMALL-SIGNAL
 PULSE RESPONSE†

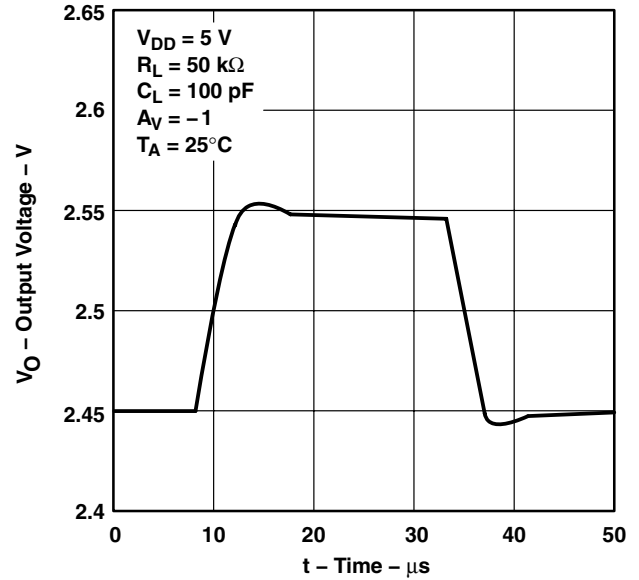


Figure 45

INVERTING SMALL-SIGNAL
 PULSE RESPONSE

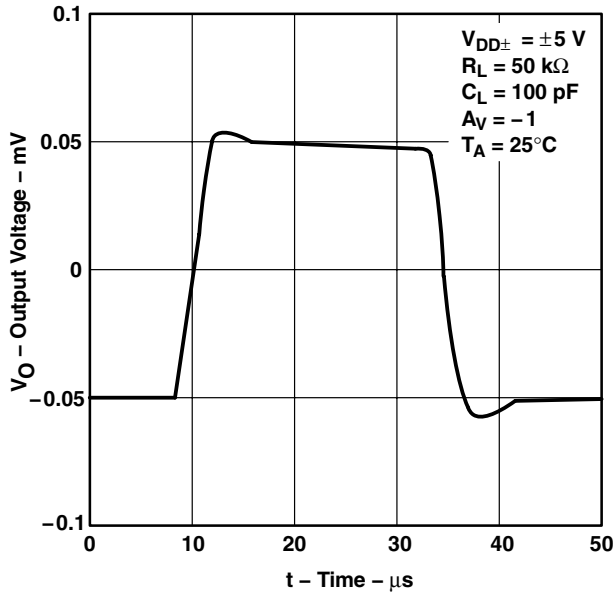


Figure 46

VOLTAGE-FOLLOWER SMALL-SIGNAL
 PULSE RESPONSE†

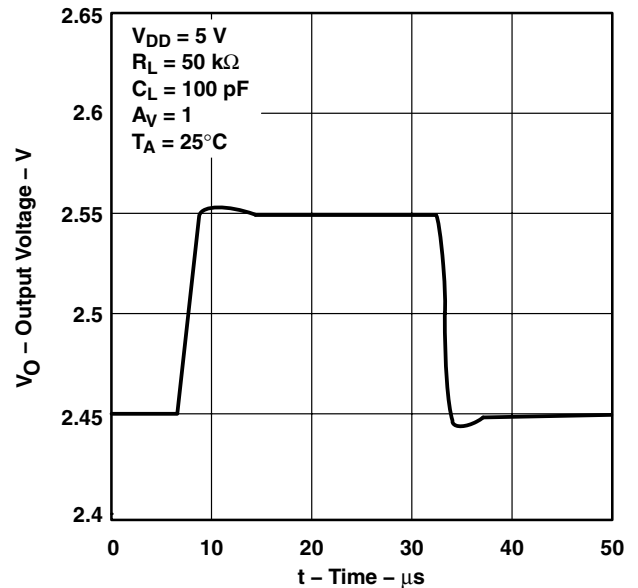


Figure 47

† For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.

TLC225x-Q1, TLC225xA-Q1
Advanced LinCMOS™ RAIL-TO-RAIL
VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

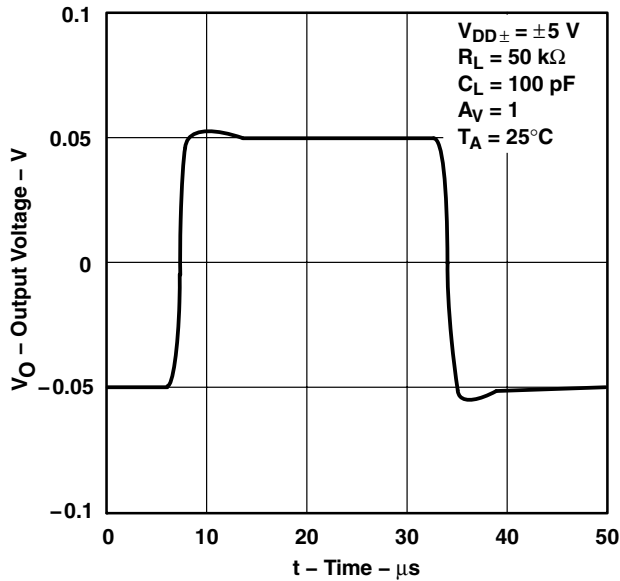


Figure 48

EQUIVALENT INPUT NOISE VOLTAGE† vs FREQUENCY

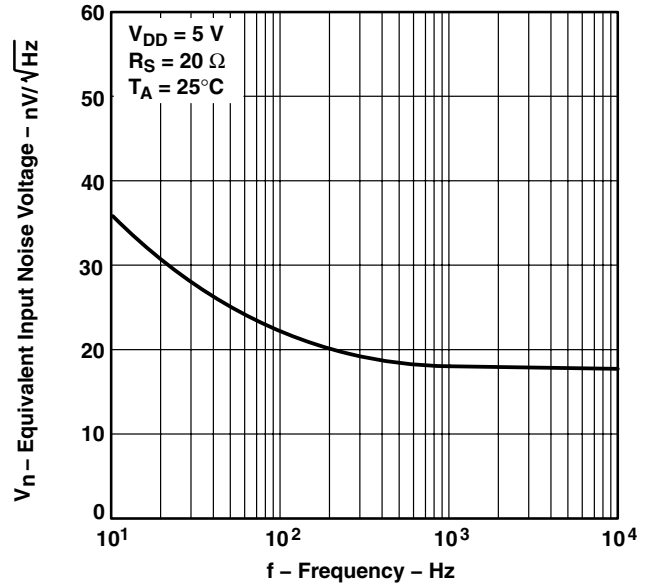


Figure 49

EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY

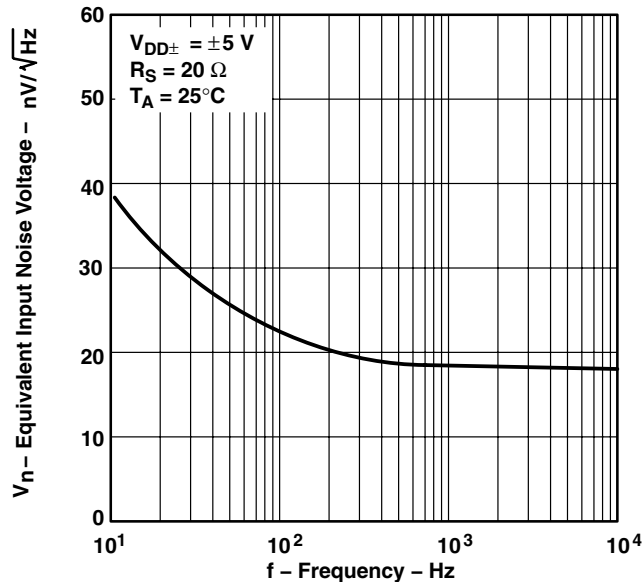


Figure 50

EQUIVALENT INPUT NOISE VOLTAGE OVER A 10-SECOND PERIOD†

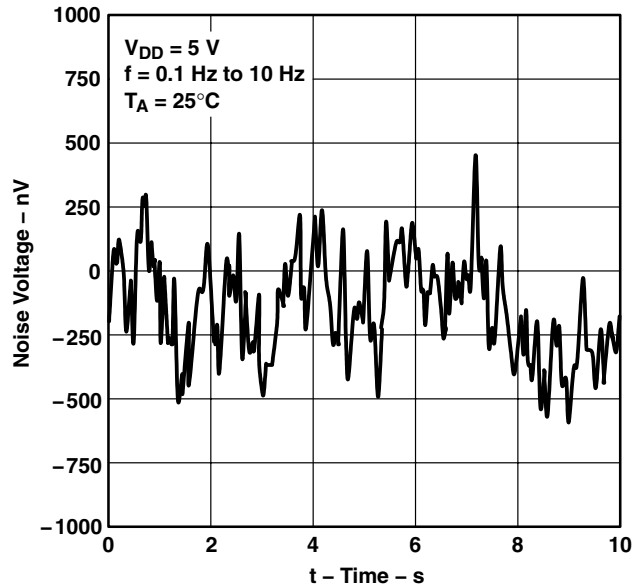
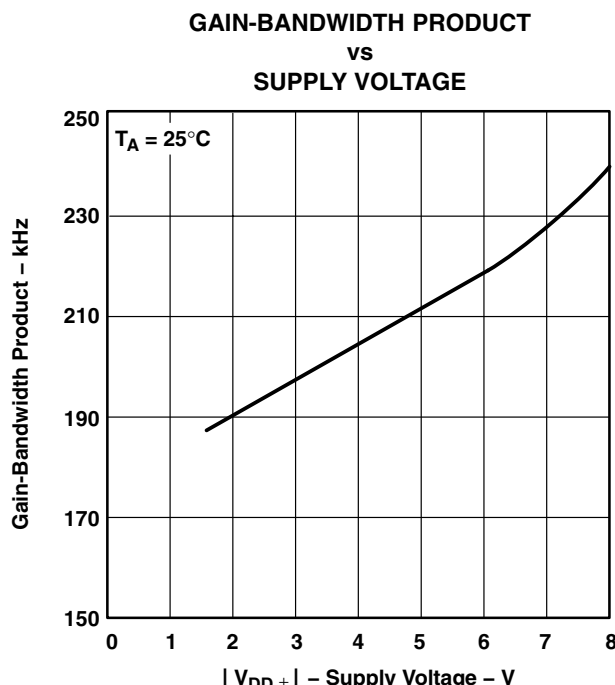
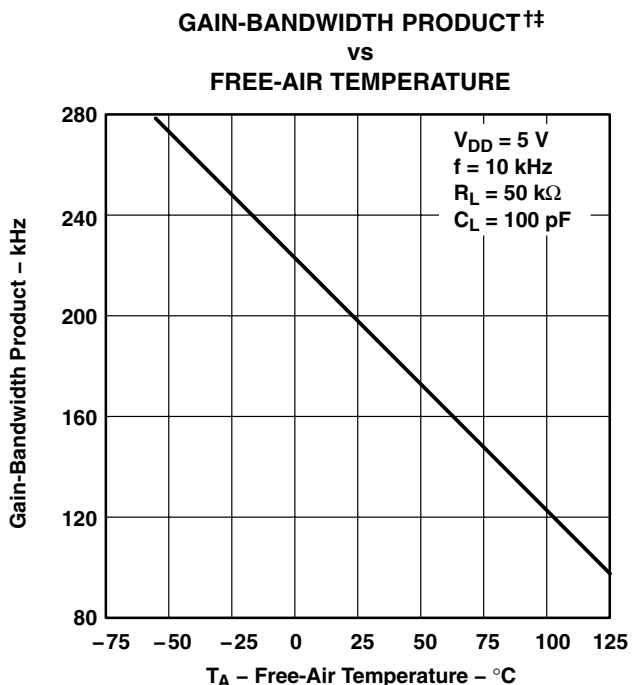
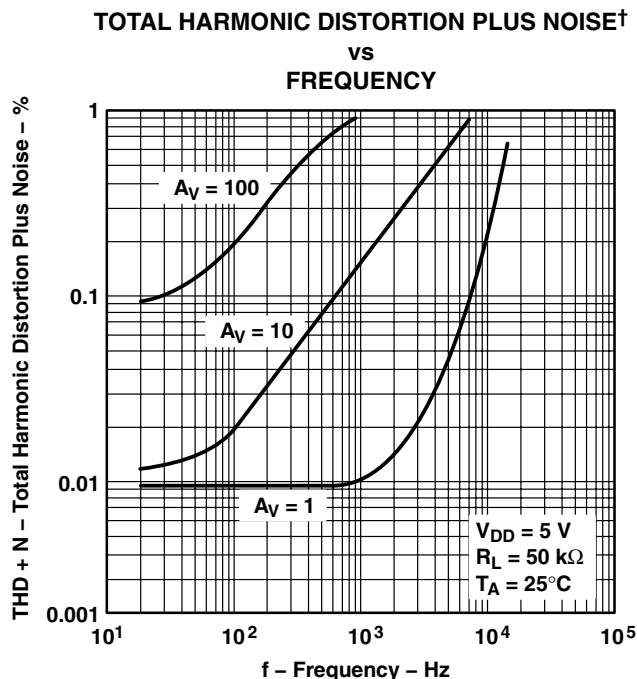
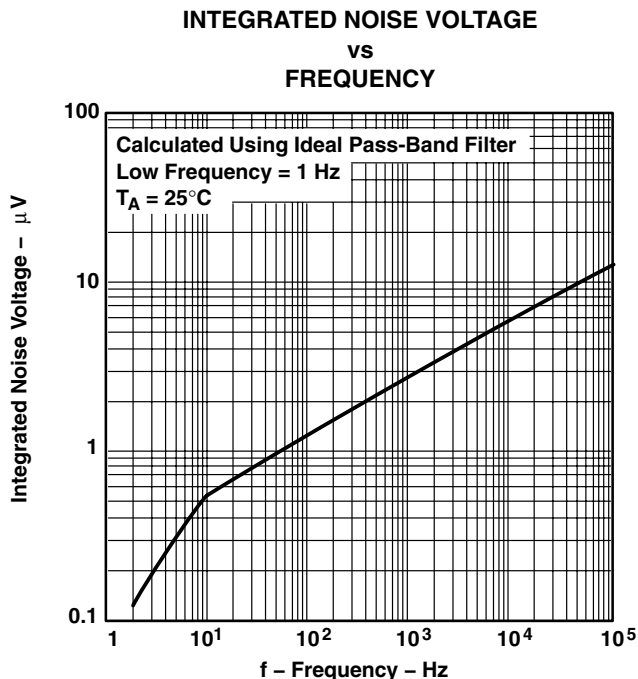


Figure 51

† For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V.



TYPICAL CHARACTERISTICS



† For curves where $V_{DD} = 5\text{ V}$, all loads are referenced to 2.5 V .

‡ Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

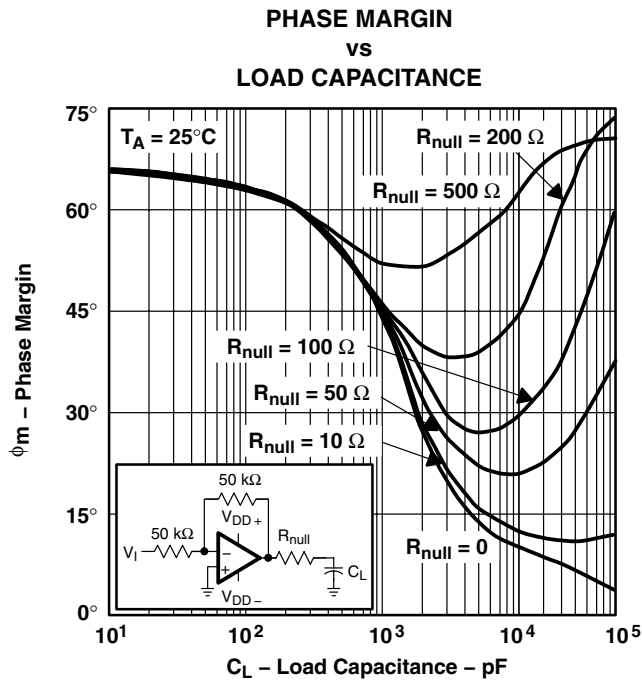


Figure 56

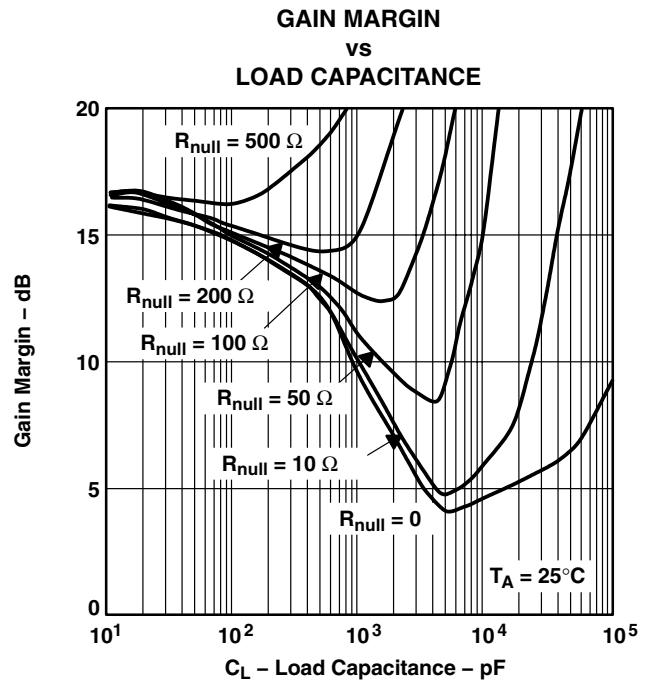


Figure 57

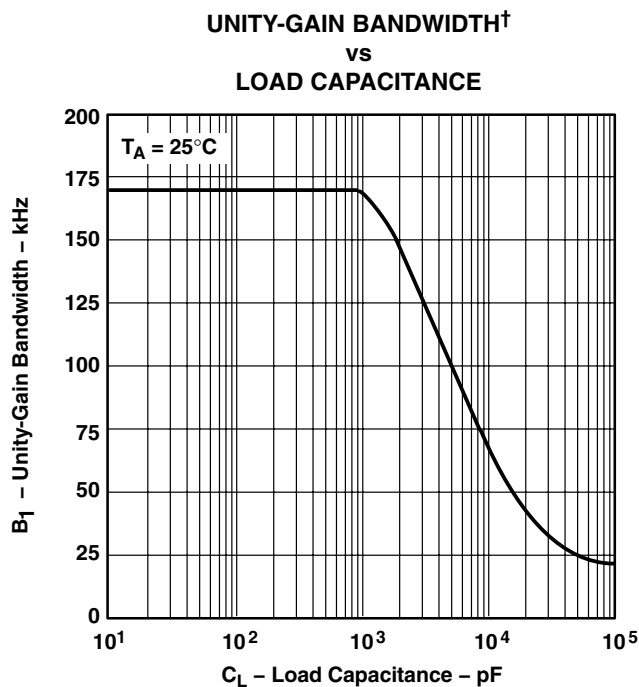


Figure 58

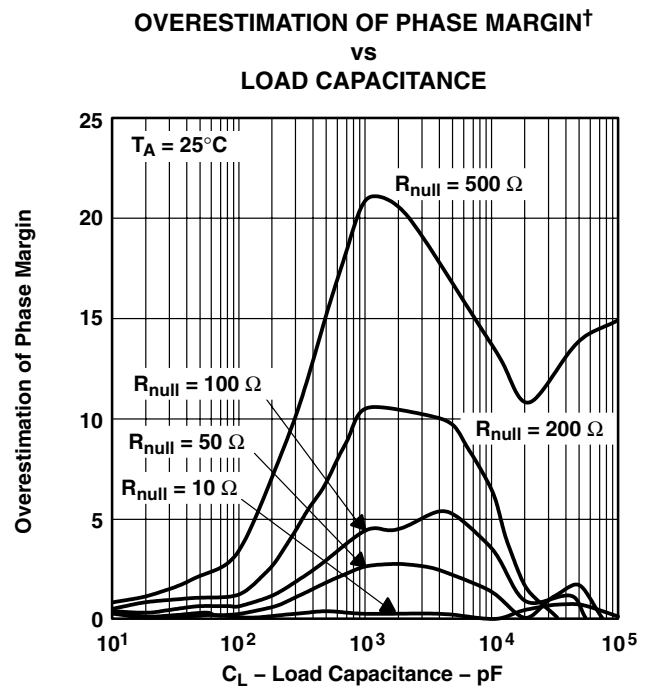


Figure 59

† See application information

APPLICATION INFORMATION

driving large capacitive loads

The TLC225x is designed to drive larger capacitive loads than most CMOS operational amplifiers. Figure 56 and Figure 57 illustrate its ability to drive loads up to 1000 pF while maintaining good gain and phase margins ($R_{null} = 0$).

A smaller series resistor (R_{null}) at the output of the device (see Figure 60) improves the gain and phase margins when driving large capacitive loads. Figure 56 and Figure 57 show the effects of adding series resistances of 10 Ω , 50 Ω , 100 Ω , 200 Ω , and 500 Ω . The addition of this series resistor has two effects: the first is that it adds a zero to the transfer function and the second is that it reduces the frequency of the pole associated with the output load in the transfer function.

The zero introduced to the transfer function is equal to the series resistance times the load capacitance. To calculate the improvement in phase margin, equation 1 can be used.

$$\Delta\phi_{m1} = \tan^{-1} \left(2 \times \pi \times \text{UGBW} \times R_{null} \times C_L \right) \quad (1)$$

Where :

- $\Delta\phi_{m1}$ = Improvement in phase margin
- UGBW = Unity-gain bandwidth frequency
- R_{null} = Output series resistance
- C_L = Load capacitance

The unity-gain bandwidth (UGBW) frequency decreases as the capacitive load increases (see Figure 58). To use equation 1, UGBW must be approximated from Figure 58.

Using equation 1 alone overestimates the improvement in phase margin, as illustrated in Figure 59. The overestimation is caused by the decrease in the frequency of the pole associated with the load, thus providing additional phase shift and reducing the overall improvement in phase margin.

Using Figure 60, with equation 1 enables the designer to choose the appropriate output series resistance to optimize the design of circuits driving large capacitance loads.

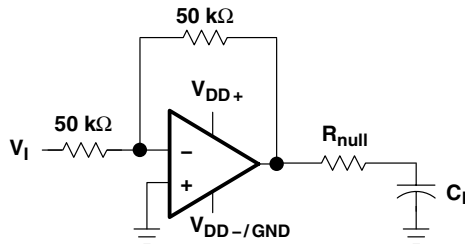


Figure 60. Series-Resistance Circuit

TLC225x-Q1, TLC225xA-Q1 Advanced LinCMOS™ RAIL-TO-RAIL VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using MicroSim *Parts*™, the model generation software used with MicroSim *PSPice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 61 are generated using the TLC225x typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 4: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

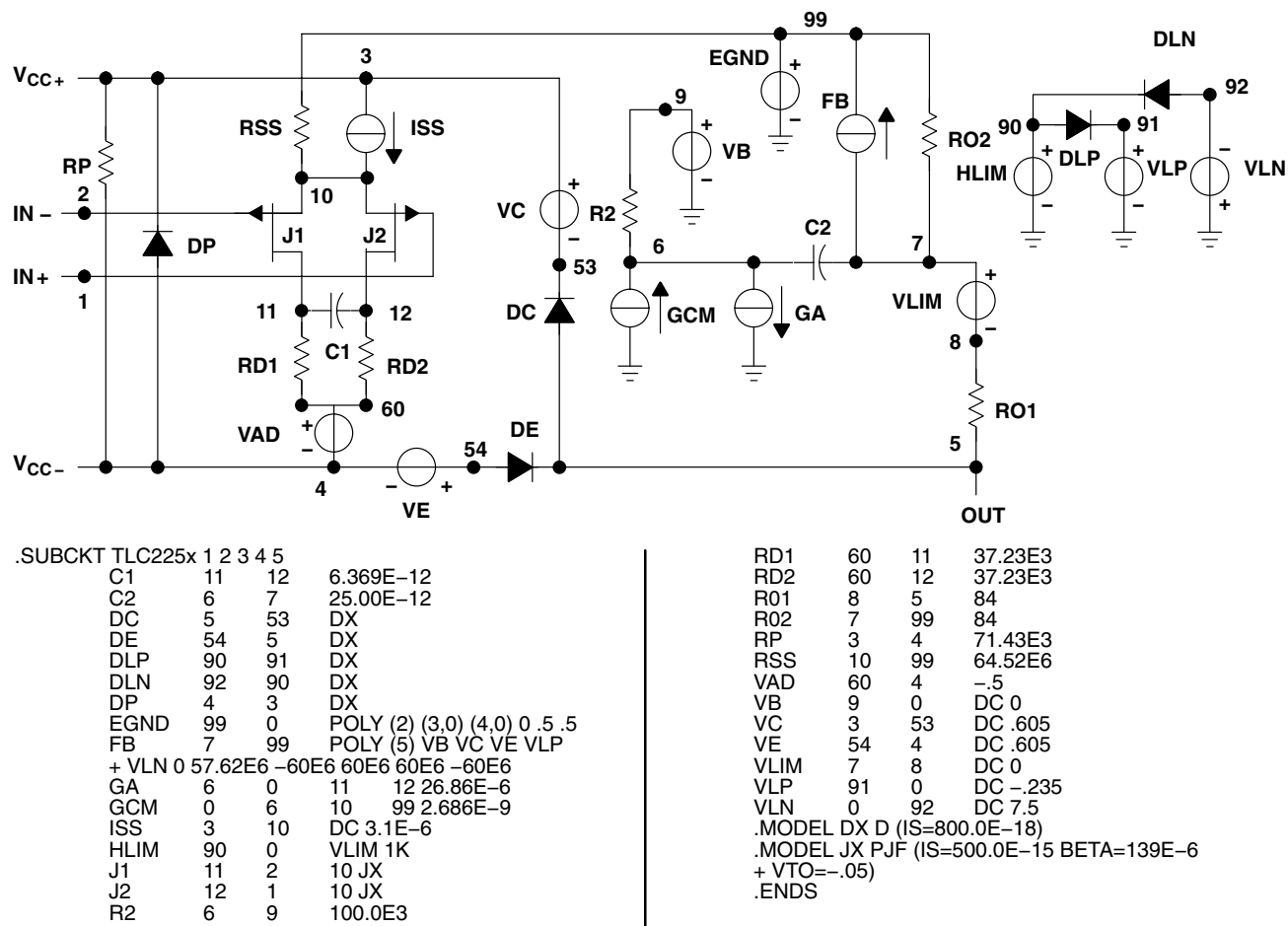


Figure 61. Boyle Macromodel and Subcircuit

PSPice and *Parts* are trademarks of MicroSim Corporation.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265
POST OFFICE BOX 1443 • HOUSTON, TEXAS 77251-1443

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLC2252AQDRG4Q1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2252AQ	Samples
TLC2252AQDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2252AQ	Samples
TLC2252AQPWRG4Q1	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2252AQ	Samples
TLC2254AQPWRQ1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2254AQ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TLC2252A-Q1, TLC2254A-Q1 :

- Catalog : [TLC2252A](#), [TLC2254A](#)
- Enhanced Product : [TLC2252A-EP](#), [TLC2254A-EP](#)
- Military : [TLC2252AM](#), [TLC2254AM](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC2252AQPWRG4Q1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TLC2254AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC2252AQPWRG4Q1	TSSOP	PW	8	2000	356.0	356.0	35.0
TLC2254AQPWRQ1	TSSOP	PW	14	2000	356.0	356.0	35.0

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040064-3/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4211284-2/G 08/15

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

- Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
- This dimension does not include interlead flash.
- Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PW0008A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4221848/A 02/2015

NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- Reference JEDEC registration MO-153, variation AA.

EXAMPLE BOARD LAYOUT

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221848/A 02/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2024, Texas Instruments Incorporated